



Sectoral Operational Programme
„Increase of Economic Competitiveness”
“Investments for Your Future”



Extreme Light Infrastructure – Nuclear Physics (ELI-NP)

Project co-financed by the European Regional Development Fund



ELI-NP GAMMA BEAM SYSTEM: NEW FACILITY FOR NUCLEAR PHYSICS RESEARCH – CURRENT STATUS

ELI-NP Gamma Beam System



Provider – EuroGammaS Association

Academic Institutions

INFN (Italy), Sapienza University (Italy), CNRS (France)

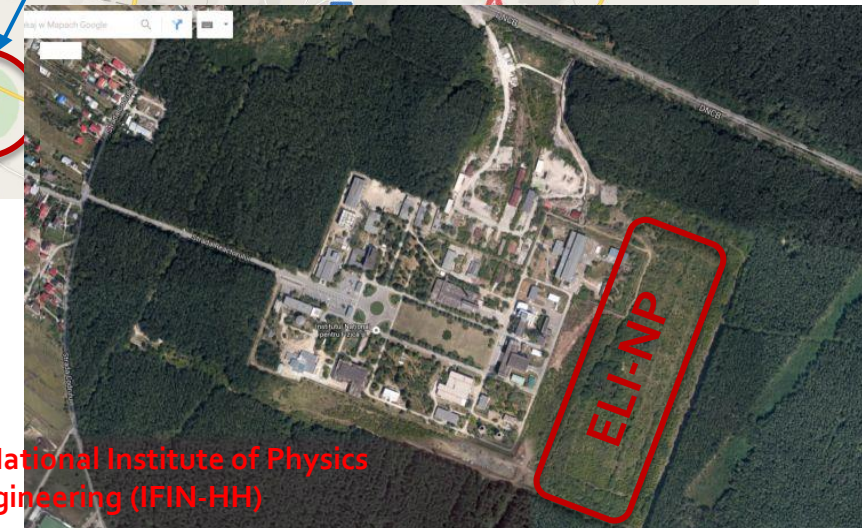
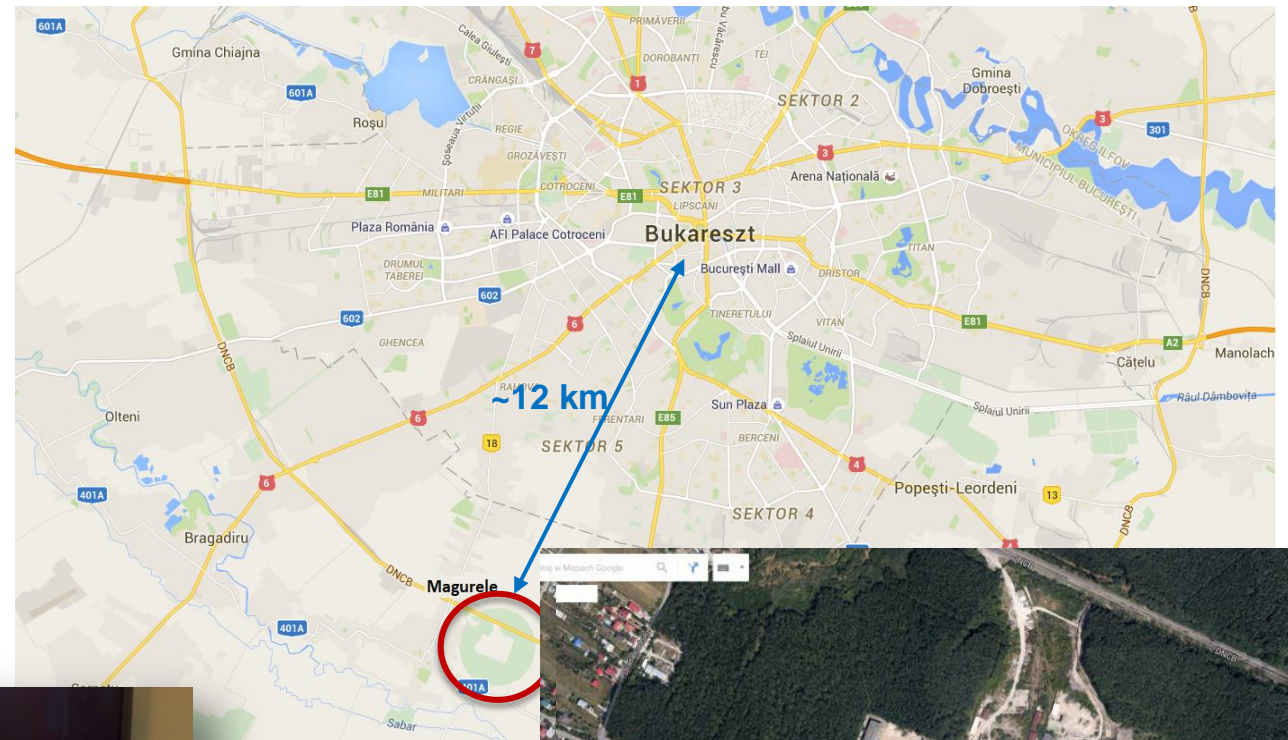
Industrial Partners

ACP Systems (France), ALSYOM (France),
COMEB (Italy), ScandiNova Systems (Sweden)

and several Sub-Contractors:

Alba (Spain), STFC (UK)

Amplitude Systems (France), Amplitude Technology (France), iTech (Slovenia), Cosylab (Slovenia), Danfysik (Denmark), M&W Group (Italy), Menlo Systems (Germany), RI (Germany),



Horia Hulubei National Institute of Physics and Nuclear Engineering (IFIN-HH)



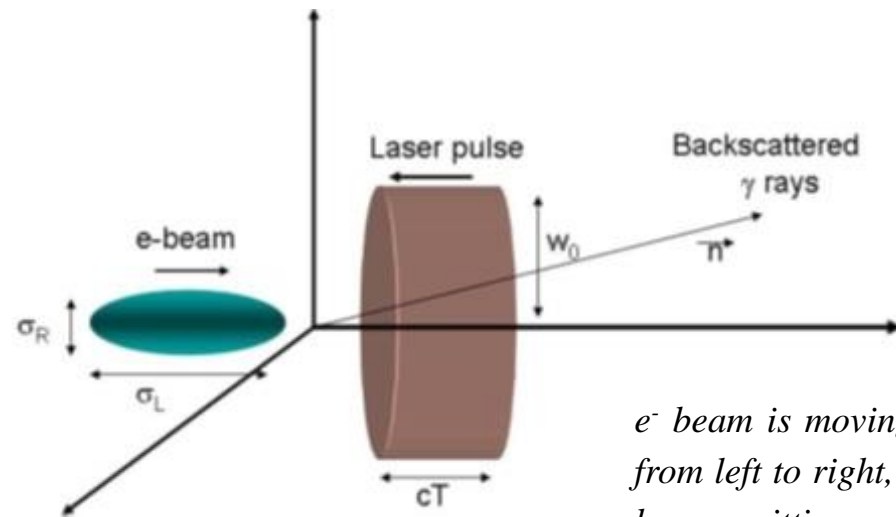
19/03/2014



Gamma Beam System – Basic Concept

Compton backscattering between a relativistic electron bunch and a high power laser pulse.

Compton backscattering geometry



e^- beam is moving at a relativistic speed from left to right, colliding with a photon beam emitting scattered radiation mainly in the direction of motion of the e^- beam.

Laser pulse (3.5ps) energy:

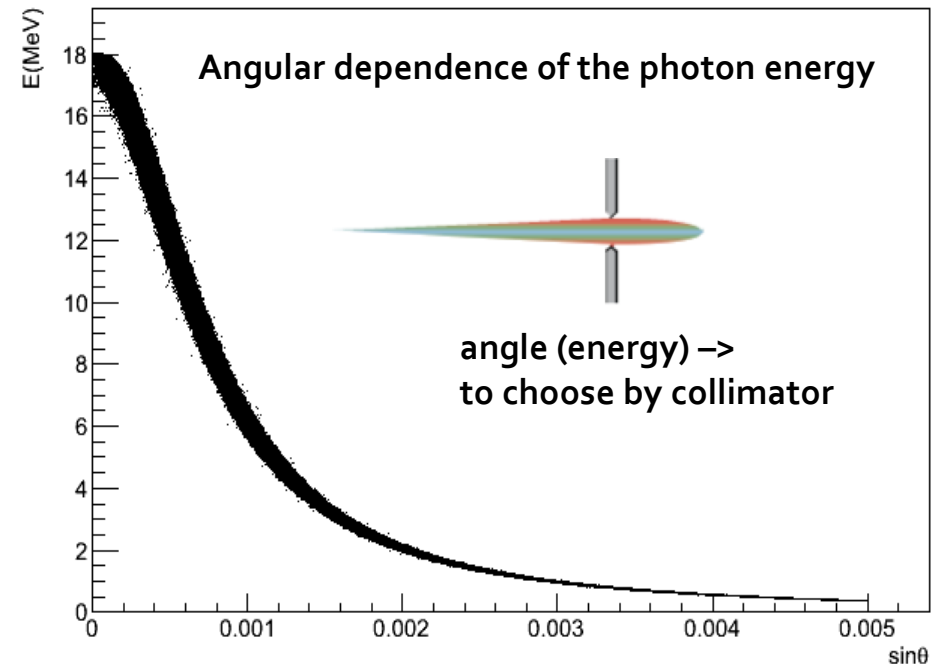
0.2J
 (2.4eV, 515nm – green)
 2 x 0.2J

$E_e \sim 300 \text{ MeV} \Rightarrow E_\gamma < 3.5 \text{ MeV}$ (Low Energy Branch)

$E_e \sim 720 \text{ MeV} \Rightarrow E_\gamma \leq 19 \text{ MeV}$ (High Energy Branch)

Low cross section ($\sim 10^{-25} \text{ cm}^2$)

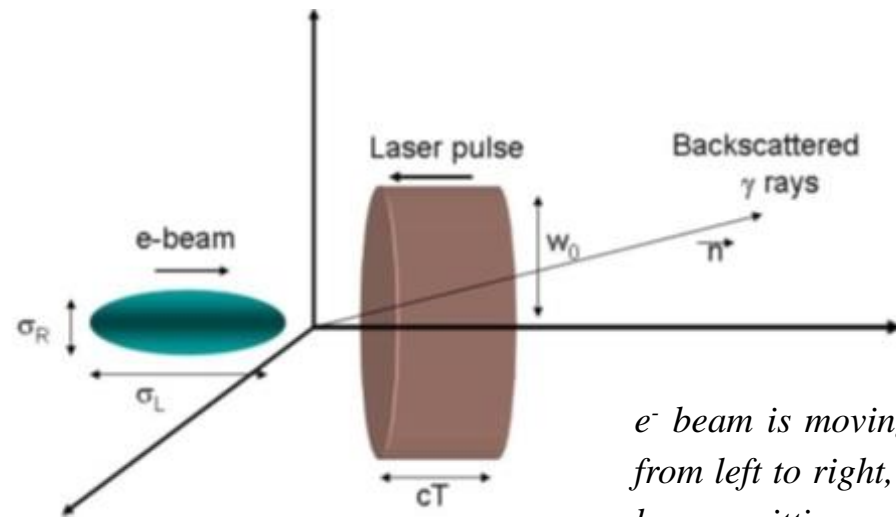
→ need of high density of electron and photon beams



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Result:

generation of high brilliance γ -ray beam with number of advantages over the more conventional bremsstrahlung sources, which are based on impinging the electron beam onto a solid target of high Z material:

- ✘ good and controllable monochromaticity,
- ✘ easy tunability,
- ✘ higher collimation
- ✘ full control of the gamma photon polarization.

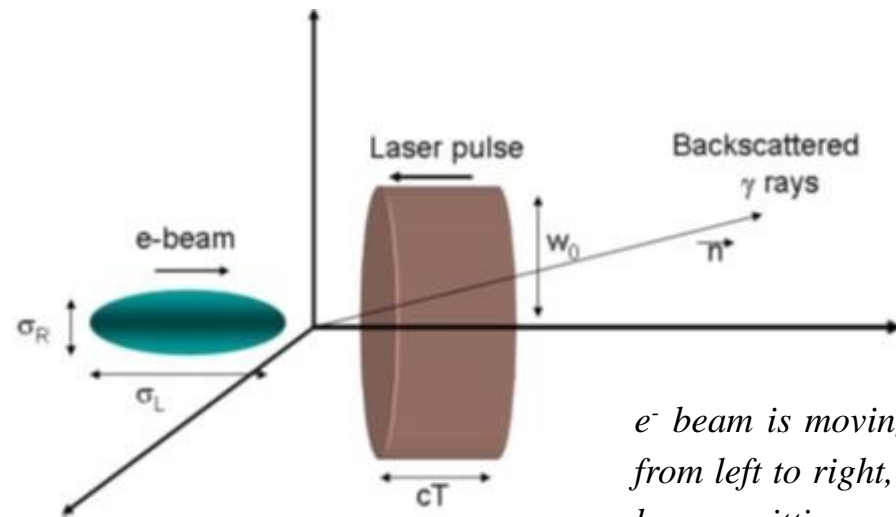
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Photon Energy	up to 19.5 MeV	Branch)
Spectral Density	10^4 ph/sec/eV	
Bandwidth (rms)	$\leq 0.5\%$	
# photons / shot within FWHM bdw.	$2.6 \cdot 10^5$ (max)	
# photons / sec within FWHM bdw.	$8.3 \cdot 10^8$ (max)	
Source rms size	$10 \div 30 \mu\text{m}$	
Source rms divergence	$30 \div 200 \mu\text{rad}$	
Peak brilliance ($N_{\text{ph}}/\text{sec mm}^2 \text{ mrad}^2 0.1\%$)	$10^{20} \div 10^{23}$	
Pulse length (rms)	$0.7 \div 1.5$ ps	
Linear polarization	$> 99\%$	
Repetition Rate	100 Hz	
Source position transverse jitter	$< 5 \mu\text{m}$	
Energy jitter pulse-to-pulse	$< 0.2 \%$	
# pulses per macro-pulse	32	
Pulse-to-pulse separation	16 ns	

Low cross section ($\sim 10^{-25} \text{ cm}^2$)

→ need of high density of electron and photon beams

ELI-NP-GBS Electron Accelerator



Electron beam parameters at Interaction Points

Energy	up to 720 MeV
Bunch charge	250 pC
Bunch length	1 ps
Norm. transverse emittance	0.4 mm·mrad
Bunch energy spread	0.04 ÷ 0.1 %
Focal spot size	~ 15 μm
Number of bunches	32
Bunch-to-bunch distance	16 ns
Energy variation along macro-bunch	0.1%
Energy jitter shot to shot	0.1%
Time arrival jitter	< 0.5 ps
Pointing jitter	1 μm
Bunch rep rate	100 Hz

We need:

- high brightness (high charge, low emittance, low energy spread) and high phase space density electron beam carrying 250pC per bunch in bunch trains of 32 bunches per RF pulse, focused down to spot sizes of about 15μm.
- laser beam of high intensity, very brilliant, high repetition rate.

The **Gamma Beam System** is based on warm RF linac operated at C-band with S-band photo-injector.

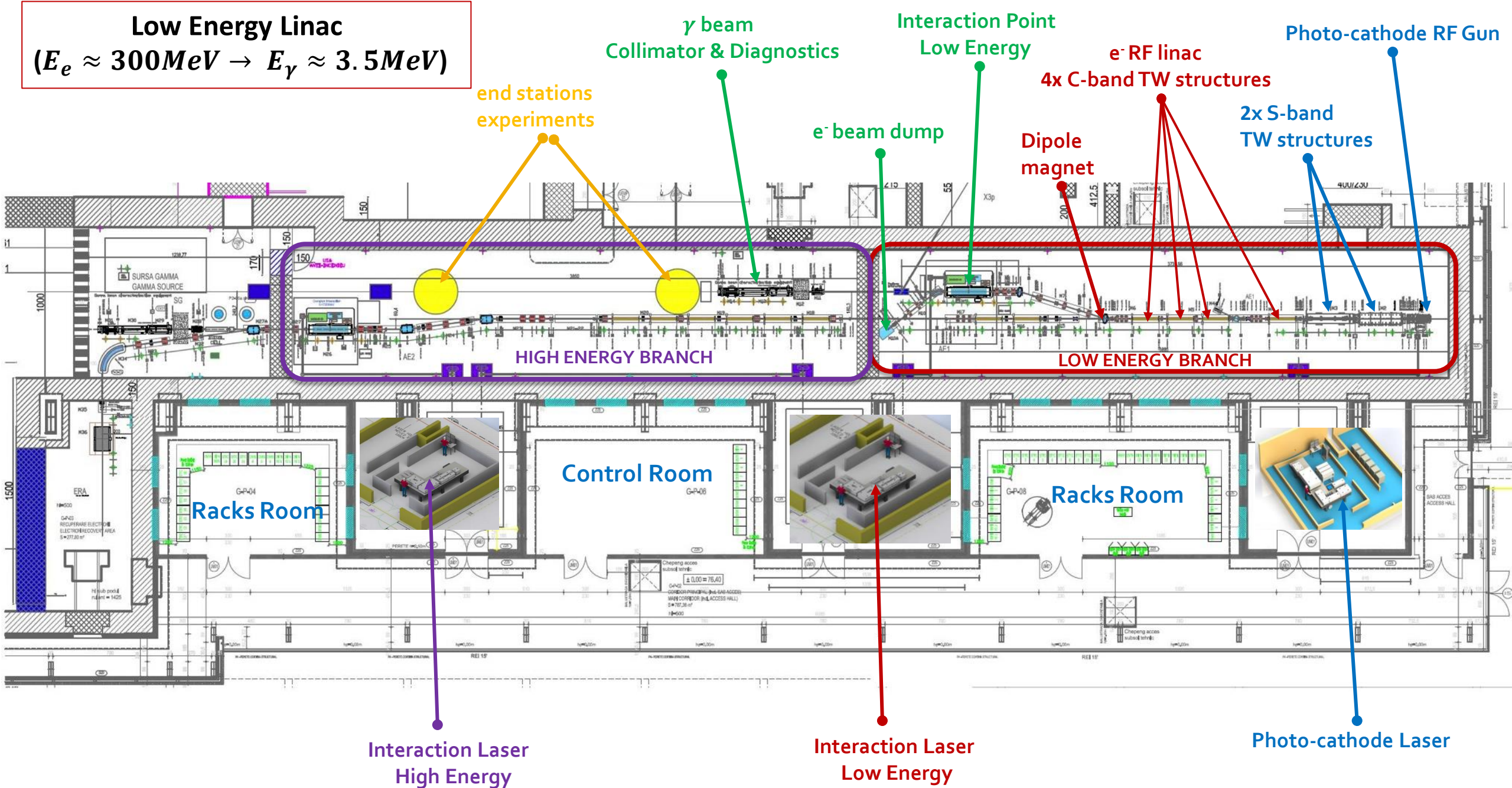


Ti:sapphire laser for photocathode RF gun

Output: ~10ps pulse duration in UV range (266nm), 150μJ/pulse, sequence of trains made of 32 pulses separated by 16ns @100Hz rep. rate.

Yb:YAG lasers for Interaction Points with 3.5 ps pulse duration (FWHM) at 515 nm, 0.2J, 100Hz, 0.1% (rms) bandwidth, and pulse energy stability of 1%.

Low Energy Linac
 $(E_e \approx 300\text{MeV} \rightarrow E_\gamma \approx 3.5\text{MeV})$



end stations experiments

γ beam Collimator & Diagnostics

e^- beam dump

Interaction Point Low Energy

Dipole magnet

e^- RF linac
4x C-band TW structures

2x S-band TW structures

Photo-cathode RF Gun

HIGH ENERGY BRANCH

LOW ENERGY BRANCH

Racks Room

Control Room

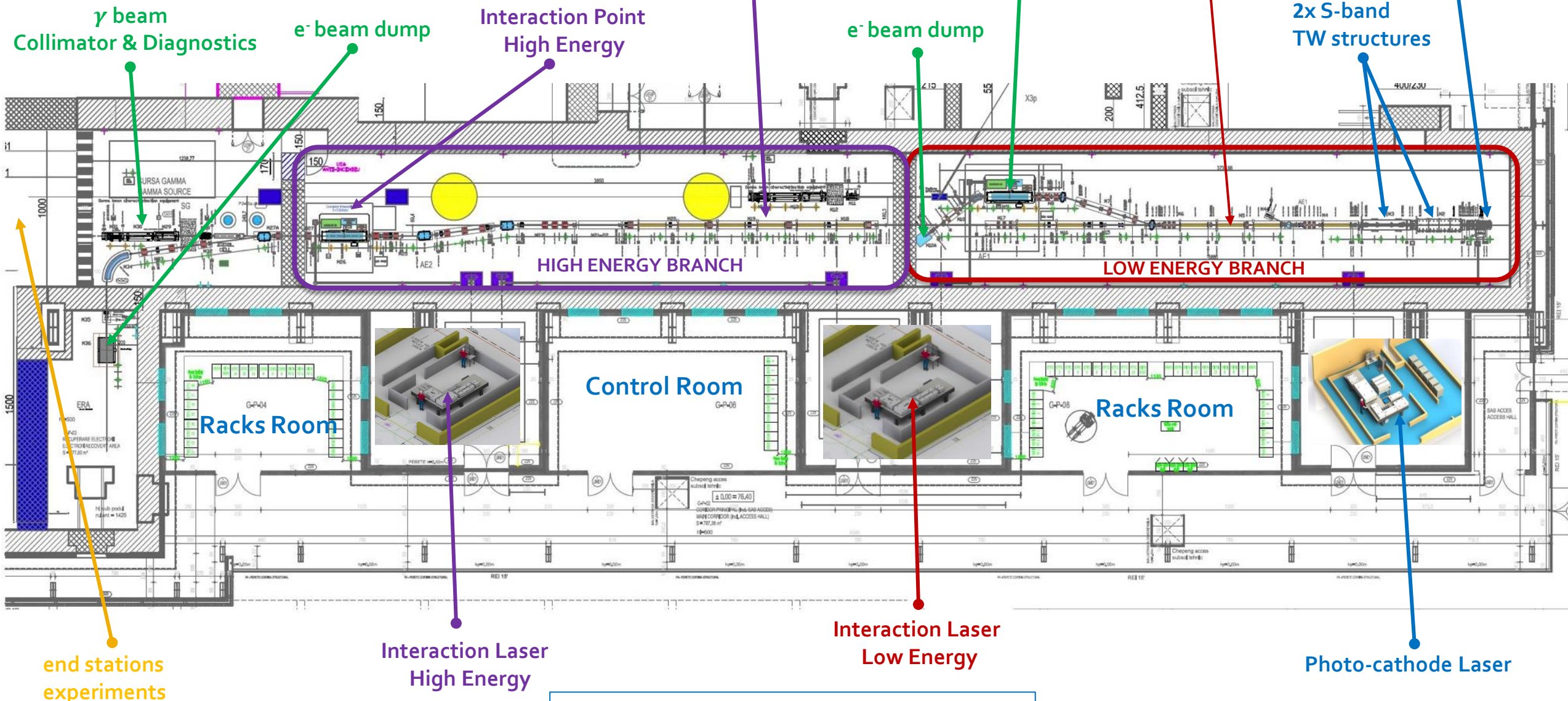
Racks Room

Photo-cathode Laser

Interaction Laser High Energy

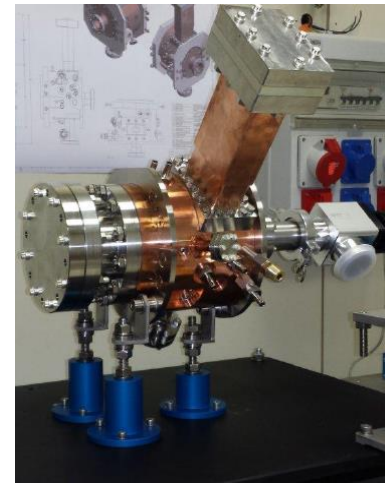
Interaction Laser Low Energy


High Energy Linac
 $(E_e \approx 720\text{MeV} \rightarrow E_\gamma \approx 18\text{MeV})$



Master Clock synchronization @ < 1ps

Photo-cathode RF Gun

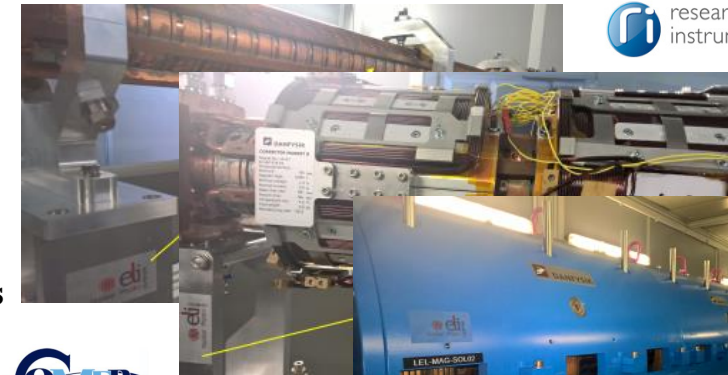


1.6-cell standing-wave RF cavity, working in S-band at 2.856 GHz. 

high gradient: 120 MV/m; 100Hz
photo-cathode: OFHC Copper


S-band injector – 2 x TW accelerating structures

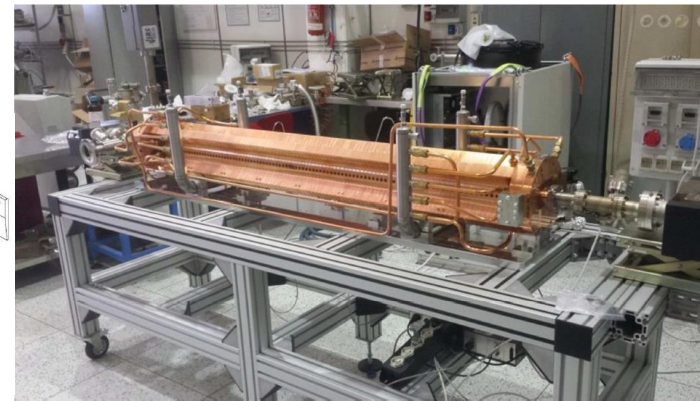
Dual-symmetric feeding – min. of multipole effects.
Long bunch at the photo-cathode (10ps) => to control the emittance growth due to space charge effects.
S-band injector – reduction of the bunch length (1ps) by the velocity bunching technique.



 research instruments

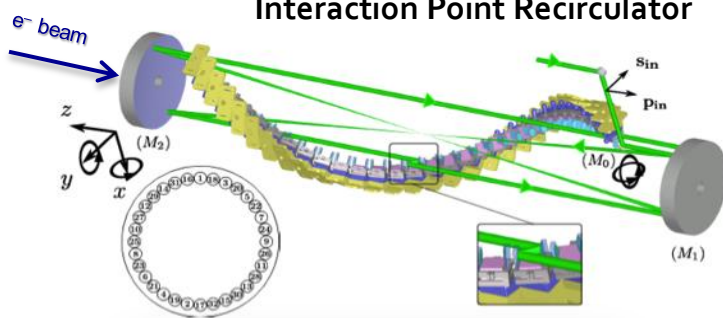
C-band linac – 12 x TW acc. structures

Effective damping of HOM dipole modes 

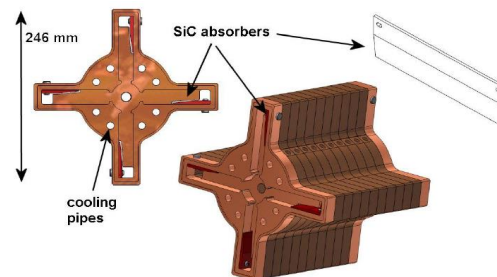


D.Alesini et al., "Design and RF Test of Damped C-band Accelerating Structures for the ELI-NP Linac"

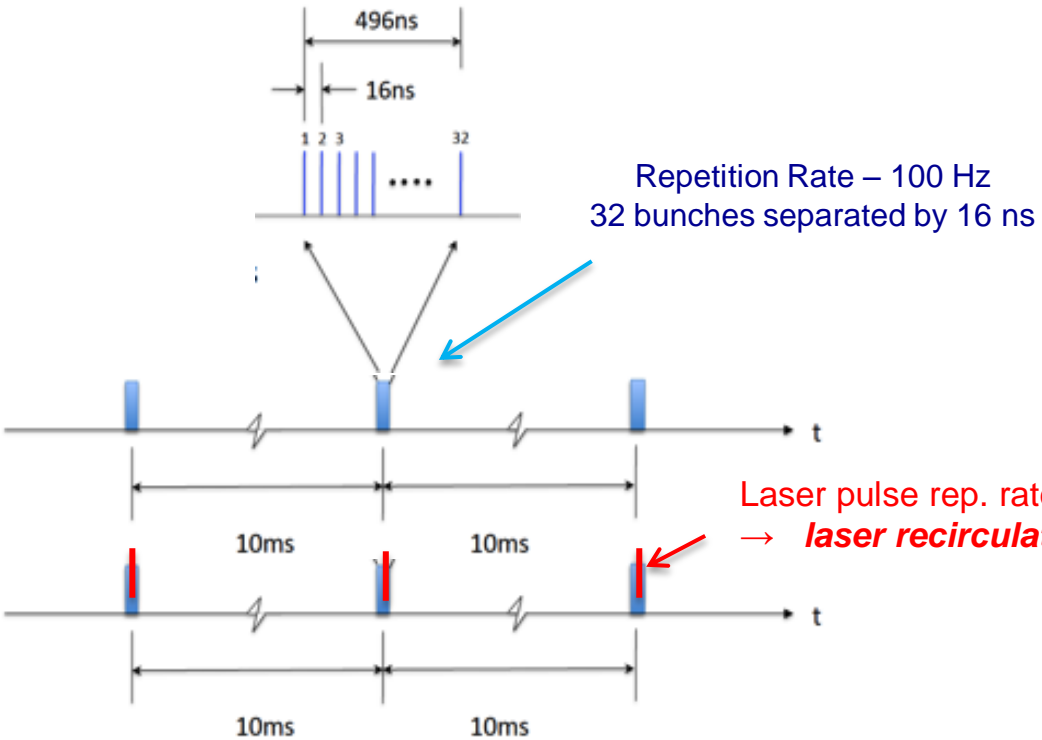
Interaction Point Recirculator



Waveguide dumping system => excited dipole modes propagate and dissipate into RF loads



Laser Recirculation at Interaction Points



Laser Recirculator:

- Highly complex optical implementation

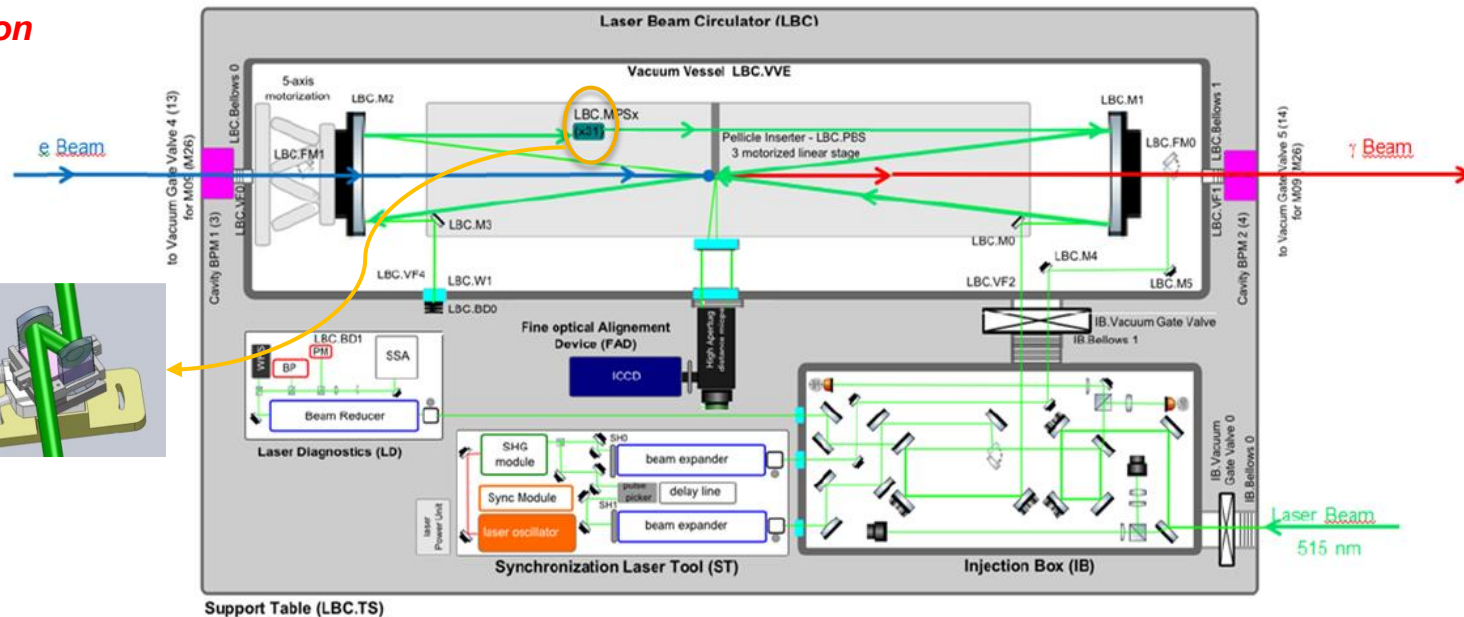
Laser Recirculator -> Single laser pulse is recirculated 32 times, synchronized with RF clock.

The laser beam is reflected and focused to the Interaction Point (IP) with the parabolic mirrors (sharing the same focal point.).

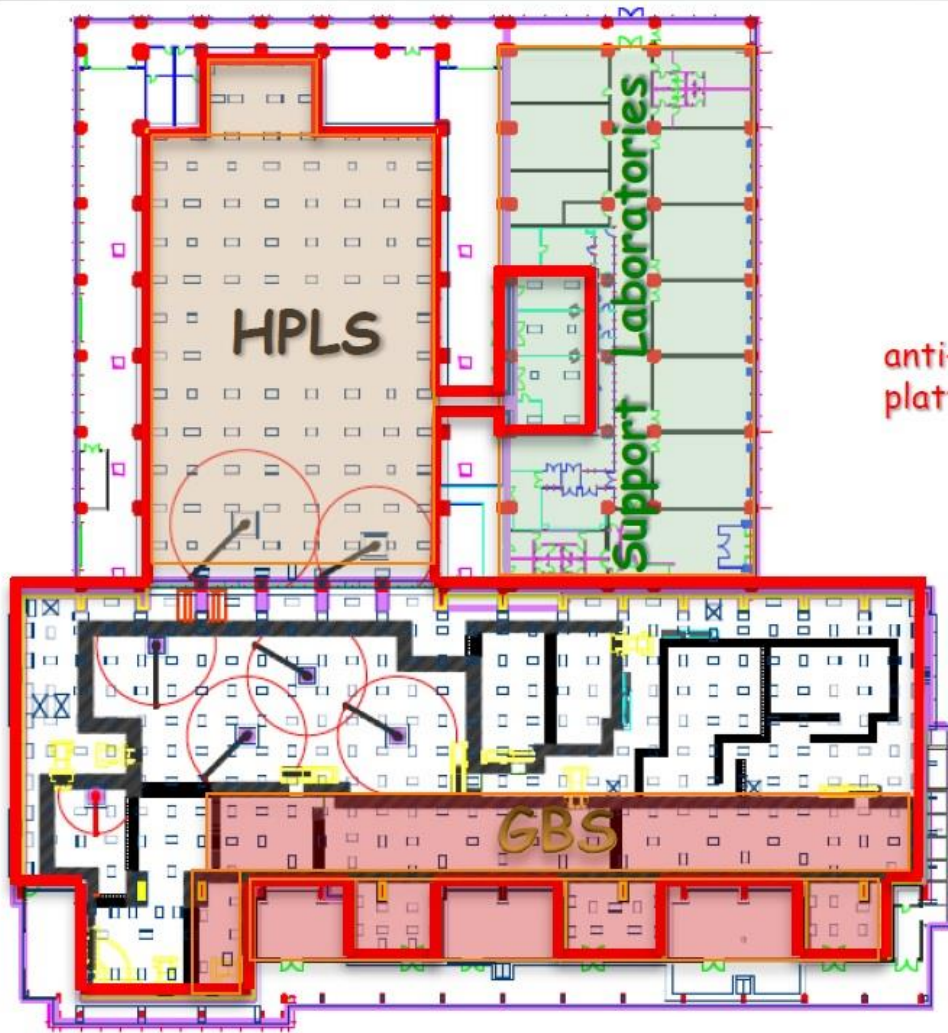
Mirror Pair System (MPS) - enables to shift the laser beam path in respect to parabolic mirrors and to delay in order to synchronize the laser pulse over the electron bunches.

2 parabolic reflectors M1& M2

- M1 fixed
- M2 : 5 degrees of freedom

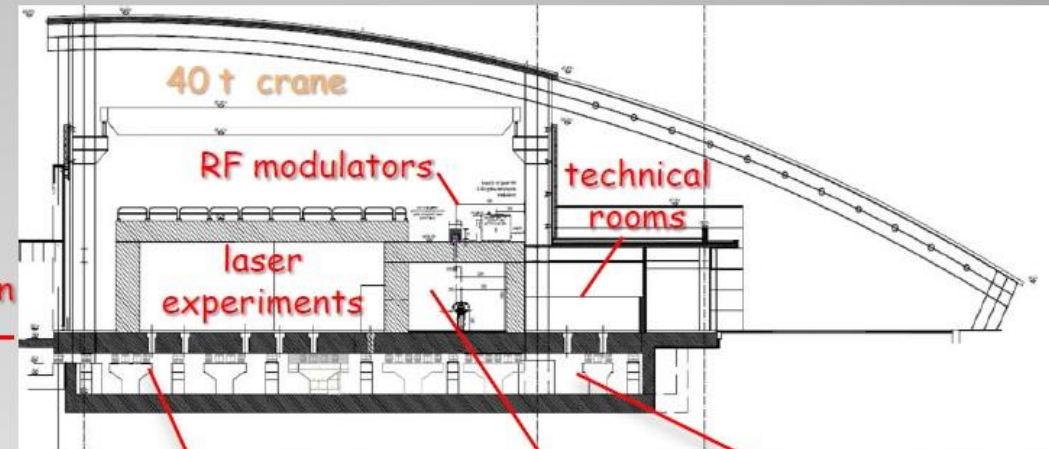


ELI-NP Facility Concept



anti-vibration platform

A - A



anti-vibration mounts

accelerator bays

basement

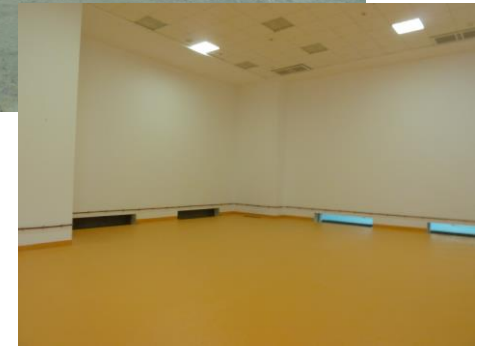
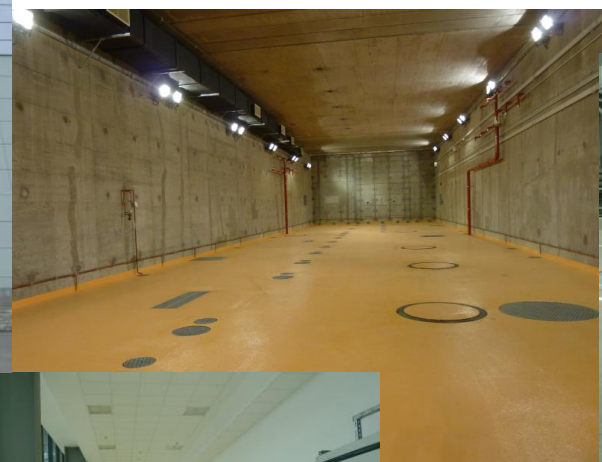


ELI -NP Main Experimental Building ~ 15,000 m

ELI-NP Facility

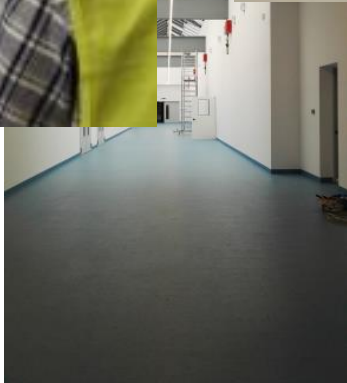


July-August 2016



Building Acceptance

June-September 2016



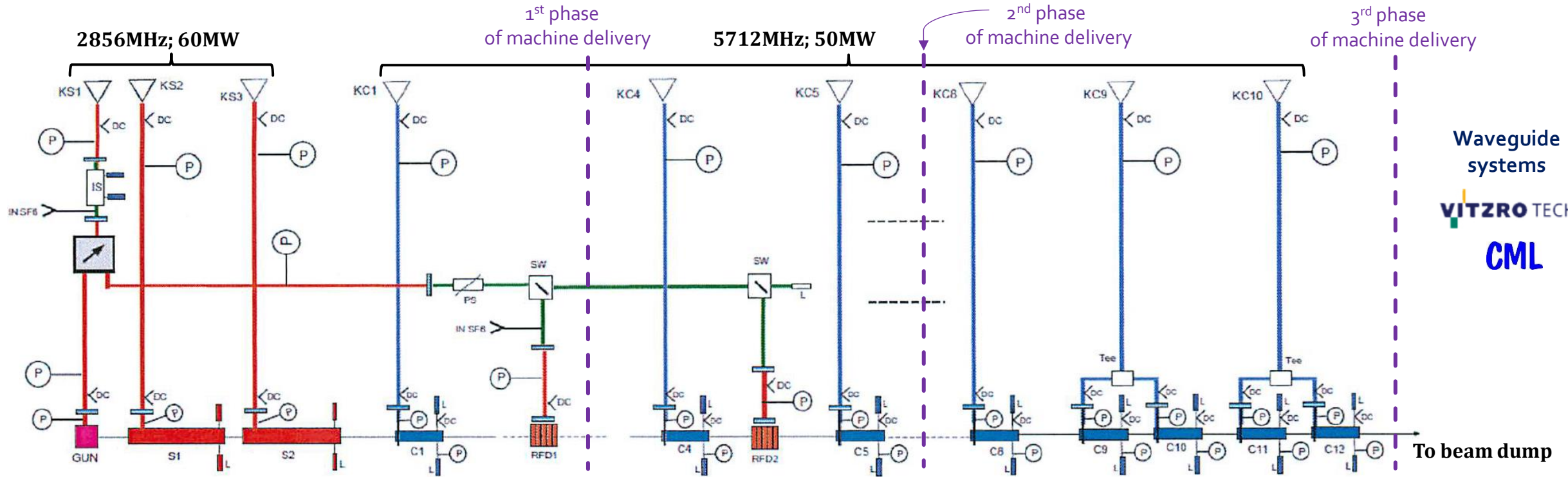
Vibration Measurements – Gerb Engineering GmbH

Laser tracker 3D scanning for check the real dimensions and volumes of the rooms.
Location of all openings etc.

Electrical measurements – grounding parameters, short-circuit current, grid voltage monitoring.

Tests of BMS, Ventilation System, Alarm system etc.

RF power distribution



Waveguide systems
VITZRO TECH
CML

- RF ceramic window
- In vacuum Cu Wg WR284
- SF6 pressurized Cu Wg WR284
- In vacuum Cu Wg WR187
- RF Load
- 60 dB Dir. Cpl
- Ferrite Isolator
- Pumping unit
- Waveguide switch
- 25 dB Variable Attenuator
- 360° Variable Phase Shifter

KLYSTRON MODULATORS	Electron Gun	Injector	Booster
Frequency [GHz]	2.856	2.856	5.712
Output Peak Power [MW]	45	60	50
Pulse length [μs]	5	1,5	0,5
Rep. Rate [Hz]	100	100	100

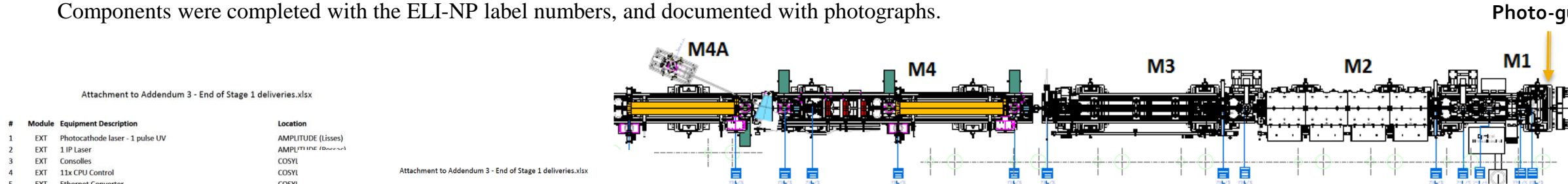
ScandiNova
TOSHIBA
 Leading Innovation >>>

Acceptance of GBS devices/components



Stage I – delivery and tests of system components corresponding to gamma beam energy min. 1MeV (by November 2015)

Components were completed with the ELI-NP label numbers, and documented with photographs.



Attachment to Addendum 3 - End of Stage 1 deliveries.xlsx

#	Module	Equipment Description	Location
1	EXT	Photocathode laser - 1 pulse UV	AMPLITUDE (Lisses)
2	EXT	1 IP Laser	AMPLITUDE (Lisses)
3	EXT	Consoles	COSYL
4	EXT	11x CPU Control	COSYL
5	EXT	Ethernet Converter	COSYL
6	EXT	Ethernet switch	COSYL
7	EXT	Fanout	COSYL
8	EXT	Monitor	COSYL
9	EXT	PLC	COSYL
10	EXT	Digitizer	COSYL
11	EXT	1 event generator Timing Central Station	COSYL
12	EXT	11 event receiver Timing Central Station	COSYL
13	EXT	Low Energy IP Laser Transport line	LAL (C)
14	EXT	Photocathode Laser Transport line	LAL (C)
15	EXT	Synchronization Main Enclosure	MENL
16	EXT	OMO related electronics	MENL
17	EXT	SFLspools and related electronics	MENL
18	EXT	SFL terminations and front end devices	MENL
19	M1	BPM Libera channel	INFN (I)
20	M1	BPM	INFN (I)
21	M1	FCT	INFN (I)
22	M1	Screen chamber	INFN (I)
23	M1	Screen chamber	INFN (I)
24	M1	H & V Corrector Magnet Type A - Hor. coil	INFN (I)
25	M1	Steerer Power Supply	INFN (I)
26	M1	Solenoid Power Supply	INFN (I)
27	M1	Steerer Power Supply	INFN (I)
28	M1	Solenoid A (2 coils)	INFN (I)
29	M1	H & V Corrector Magnet Type A - Vert. coil	INFN (I)
30	M1	Girder	INFN (I)
31	M1	Mechanical Support	INFN (I)
32	M1	Vacuum chamber	INFN (I)
33	M1	Cold cathode vacuum gauge - Agilent IMG300	INFN (I)
34	M1	Cold cathode vacuum gauge - Agilent IMG300	INFN (I)
35	M1	Thermal conductivity vacuum gauge - Agilent TC536 Pirani	INFN (I)
36	M1	Cold cathode vacuum gauge - Agilent IMG300	INFN (I)
37	M1	Thermal conductivity vacuum gauge - Agilent TC536 Pirani	INFN (I)
38	M1	Ion pump 75 l/s	INFN (I)
39	M1	Ion pump 75 l/s	INFN (I)
40	M1	4 channels Power Supply (for 4 pumps)	INFN (I)
41	M1	Pump Power Supply	INFN (I)
42	M1	Residual gas analyser	INFN (I)
43	M1	Pumping & Vent valve (MANUAL)	INFN (I)
44	M1	Pumping & Vent valve (MANUAL)	INFN (I)
45	M1	Sector Vacuum valve (PNEUMATIC)	INFN (I)
46	M1	Sector Vacuum valve (PNEUMATIC)	INFN (I)
47	M1	RF window	RI (Bo)
48	M1	S-band RF Gun cavity	RI (Bo)
49	M1	MSB1 (Modulator)	RI (Bo)
50	M1	MSB1 (Klystron)	RI (Bo)
51	M1	Directional coupler	RI (Bo)

Attachment to Addendum 3 - End of Stage 1 deliveries.xlsx

#	Module	Equipment Description	Location
52	M1	Directional coupler	RI (Bonn)
53	M1	Waveguides S-band, 1 pumping	RI (Bonn)
54	M1	RF window	RI (Bonn)
55	M1	Ion pump 20 l/s	RI (Bonn)
56	M1	Ion pump 75 l/s	RI (Bonn)
57	M1	Pump	RI (Bonn)
58	M1	Pump	RI (Bonn)
59	M2	H Corrector Type B1 Single plane	INFN (I)
60	M2	H Corrector Type B1 Single plane	INFN (I)
61	M2	Power Supply	INFN (I)
62	M2	Power Supply	INFN (I)
63	M2	1 Solenoid Power Supply	INFN (I)
64	M2	Power Supply	INFN (I)
65	M2	Power Supply	INFN (I)
66	M2	Solenoid B (12 coils)	INFN (I)
67	M2	V Corrector Type B1 Single plane	INFN (I)
68	M2	V Corrector Type B1 Single plane	INFN (I)
69	M2	Girder	INFN (I)
70	M2	Mechanical support	INFN (I)
71	M2	S-band Accelerating Structure	INFN (I)
72	M2	2 Loads (section termination)	INFN (I)
73	M2	Directional coupler	INFN (I)
74	M2	Ion pump 75 l/s	INFN (I)
75	M2	4 channels Power Supply	INFN (I)
76	M2	Directional coupler	INFN (I)
77	M2	1 T pumping S-band	INFN (I)
78	M2	Waveguide S-band	INFN (I)
79	M2	1 Pump	INFN (I)
80	M2	1 RF window	INFN (I)
81	M2	MSB2 (Modulator)	INFN (I)
82	M2	MSB2 (Klystron)	INFN (I)
83	M3	BPM Libera channel	INFN (I)
84	M3	BPM	INFN (I)
85	M3	Screen chamber	INFN (I)
86	M3	H Corrector Type B2 Single plane	INFN (I)
87	M3	H Corrector Type B2 Single plane	INFN (I)
88	M3	Steerer Power Supply	INFN (I)
89	M3	Steerer Power Supply	INFN (I)
90	M3	Steerer Power Supply	INFN (I)
91	M3	Steerer Power Supply	INFN (I)
92	M3	V Corrector Type B2 Single plane	INFN (I)
93	M3	V Corrector Type B2 Single plane	INFN (I)
94	M3	Girder	INFN (I)
95	M3	Mechanical support	INFN (I)
96	M3	Directional coupler	INFN (I)
97	M3	S-band Accelerating Structure	INFN (I)
98	M3	2 Loads (section termination)	INFN (I)
99	M3	Vacuum chambers	RI (Bo)
100	M3	Cold cathode vacuum gauge - Agilent IMG300	RI (Bo)
101	M3	Thermal conductivity vacuum gauge - Agilent	RI (Bo)
102	M3	Cold cathode vacuum gauge - Agilent IMG300	RI (Bo)

Attachment to Addendum 3 - End of Stage 1 deliveries.xlsx

#	Module	Equipment Description	Location
103	M3	Cold cathode vacuum gauge - Agilent IMG300	INFN (Frascati)
104	M3	Ion pump 75 l/s	INFN (Frascati)
105	M3	Ion pump 75 l/s	INFN (Frascati)
106	M3	Ion pump 75 l/s	INFN (Frascati)
107	M3	Ion pump 75 l/s	INFN (Frascati)
108	M3	Ion pump 75 l/s	INFN (Frascati)
109	M3	Ion pump 75 l/s	INFN (Frascati)
110	M3	Ion pump 75 l/s	INFN (Frascati)
111	M3	Ion pump 75 l/s	INFN (Frascati)
112	M3	Ion pump 75 l/s	INFN (Frascati)
113	M3	Ion pump 75 l/s	INFN (Frascati)
114	M3	Ion pump 75 l/s	INFN (Frascati)
115	M3	Ion pump 75 l/s	INFN (Frascati)
116	M3	Ion pump 75 l/s	INFN (Frascati)
117	M3	Ion pump 75 l/s	INFN (Frascati)
118	M3	Ion pump 75 l/s	INFN (Frascati)
119	M3	Ion pump 75 l/s	INFN (Frascati)
120	M3	Ion pump 75 l/s	INFN (Frascati)
121	M3	Ion pump 75 l/s	INFN (Frascati)
122	M3	Ion pump 75 l/s	INFN (Frascati)
123	M3	Ion pump 75 l/s	INFN (Frascati)
124	M3	Ion pump 75 l/s	INFN (Frascati)
125	M3	Ion pump 75 l/s	INFN (Frascati)
126	M3	Ion pump 75 l/s	INFN (Frascati)
127	M3	Ion pump 75 l/s	INFN (Frascati)
128	M3	Ion pump 75 l/s	INFN (Frascati)
129	M3	Ion pump 75 l/s	INFN (Frascati)
130	M3	Ion pump 75 l/s	INFN (Frascati)
131	M3	Ion pump 75 l/s	INFN (Frascati)
132	M3	Ion pump 75 l/s	INFN (Frascati)
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134	M3	Ion pump 75 l/s	INFN (Frascati)
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136	M3	Ion pump 75 l/s	INFN (Frascati)
137	M3	Ion pump 75 l/s	INFN (Frascati)
138	M3	Ion pump 75 l/s	INFN (Frascati)
139	M3	Ion pump 75 l/s	INFN (Frascati)
140	M3	Ion pump 75 l/s	INFN (Frascati)
141	M3	Ion pump 75 l/s	INFN (Frascati)
142	M3	Ion pump 75 l/s	INFN (Frascati)
143	M3	Ion pump 75 l/s	INFN (Frascati)
144	M3	Ion pump 75 l/s	INFN (Frascati)
145	M3	Ion pump 75 l/s	INFN (Frascati)
146	M3	Ion pump 75 l/s	INFN (Frascati)
147	M3	Ion pump 75 l/s	INFN (Frascati)
148	M3	Ion pump 75 l/s	INFN (Frascati)
149	M3	Ion pump 75 l/s	INFN (Frascati)
150	M3	Ion pump 75 l/s	INFN (Frascati)
151	M3	Ion pump 75 l/s	INFN (Frascati)
152	M3	Ion pump 75 l/s	INFN (Frascati)
153	M3	Ion pump 75 l/s	INFN (Frascati)



Acceptance of GBS devices/components

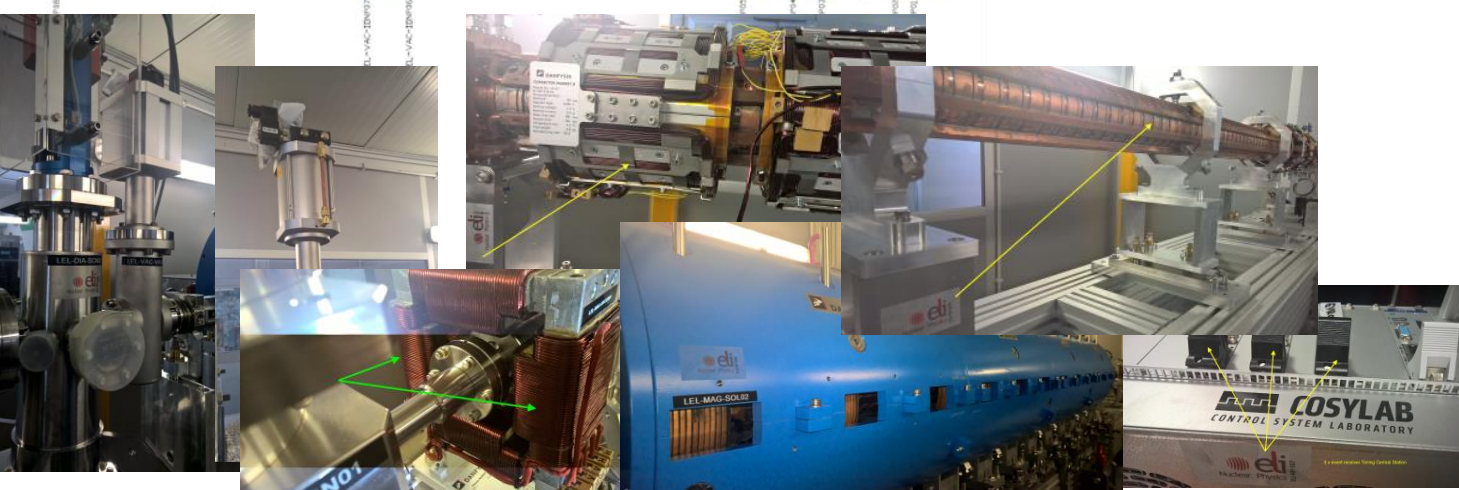
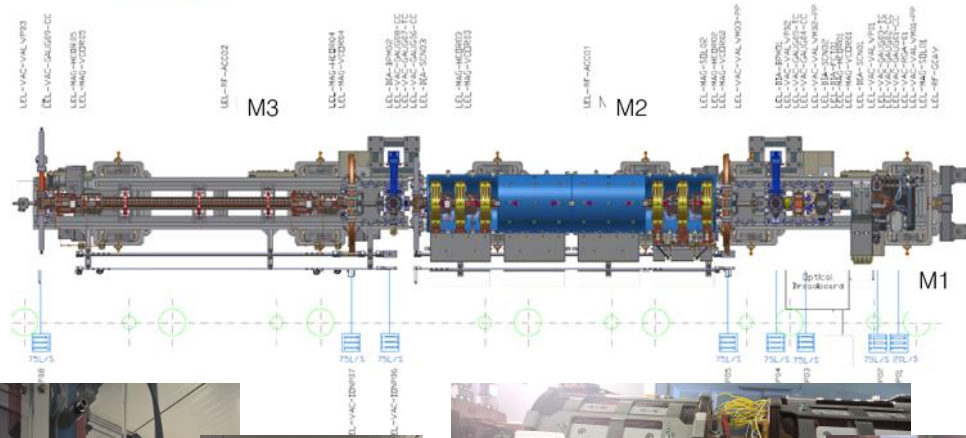


INFN, Frascati, Italy

Modules M1, M2, M3 (components mounted and aligned with laser tracker)

Every module is completed with horizontal and vertical steerers for beam position adjustment, beam position monitor system (BPM) and screens for beam profile analysis, vacuum elements, power supplies

LAYOUT



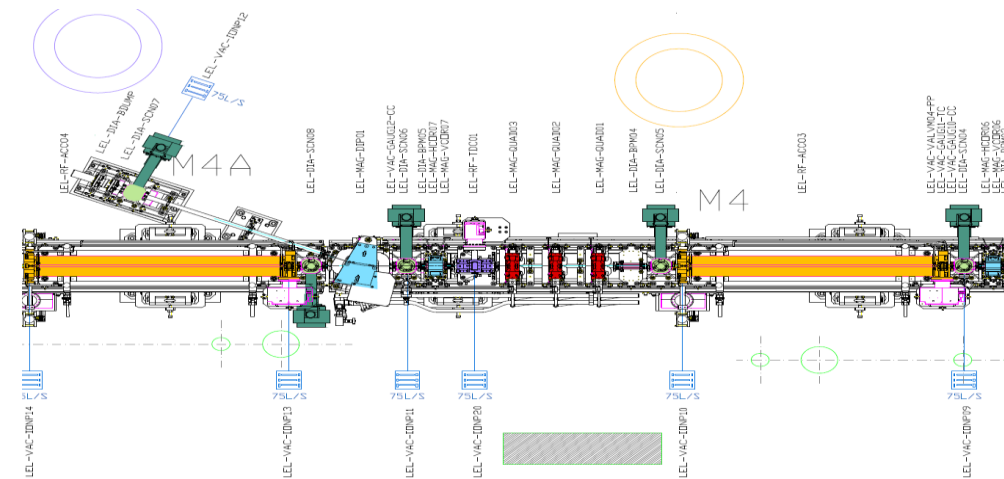
STFC, Daresbury, UK

Provided two modules M4 and M4A (mounted components and aligned with laser tracker)

M4 – C-band accelerating structure, 3x quadrupole magnets and a dipole magnet. M4A – beam dump.

Every module is completed with horizontal and vertical steerers for beam position adjustment, beam position monitor systems (BPM) and OTR screens for beam profile analysis, vacuum elements (gauges, ion pumps, manual automatic valves), power supplies.

(Stage II – modules M5 to M8 were in advanced stage of mounting.)

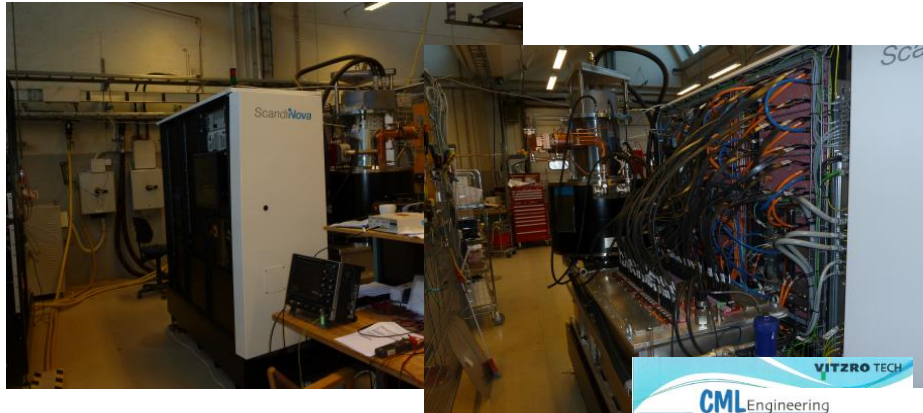


Acceptance of GBS devices/components



Scandinova, Uppsala, Sweden

- Modulators and klystrons – modulators MSB1, MSB2, MSB3, MCB1



CML Engineering
684 Rancheros Drive San Marcos, CA 92069

CERTIFICATE OF COMPLIANCE

TEST PARTS

1. MECHANICAL: ScandiNova Model: K2-2 Serial: M892-4

2. ELECTRICAL: Klystron Modulator Factory Acceptance Test Report

Model: K2-2
Serial No: M892-4

ACCEPTANCE PROTOCOL

Project: ELI-NP Gamma Beam System (Stage 3)

Subject: Acceptance of RF Units (Klystron Modulators)

ScandiNova Representative: [Signature]

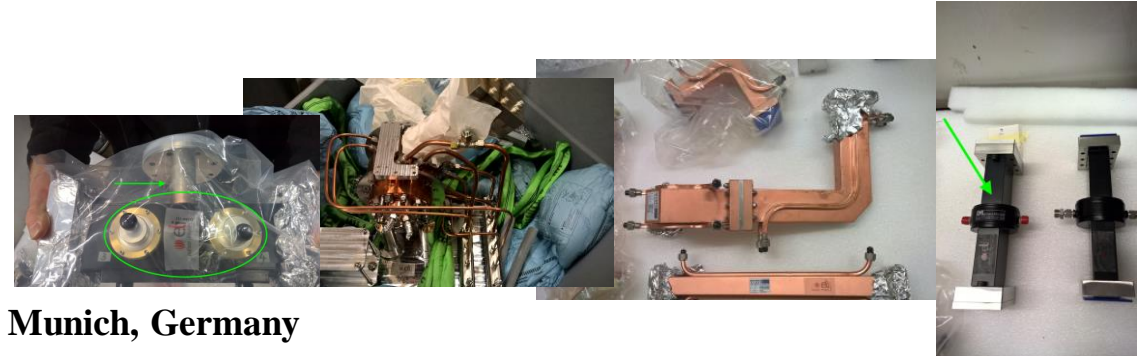
ELI-NP Representative: [Signature]

Date, signature: 26.03.2015

Place: ScandiNova Factory, Uppsala, Sweden

Research Instruments, Bonn/Bergish Gladbach, Germany

- Power conditioning of S- and C-band accelerating structures, and photo-gun
- Photo-gun, S-band structures, RF waveguides, vacuum components, directional couplers, RF windows.
- RI will install RF components in the ELI-NP building,
- Takes care of the implementation of the network of reference points for the accelerator alignment in the ELI-NP building.



Menlo Systems, Munich, Germany

- Timing systems for synchronization at femtoseconds level
- Timing distribution needed to synchronize the electron beam and the laser pulses at the interaction point with an accuracy better than 500fs.
- The system is based on Optical Master Oscillator and Stabilized Fiber Links, ensuring the synchronization of the RF and laser systems.



Cosylab, Ljubljana, Slovenia

- Delivery of the software and hardware necessary to control the modules M1 to M4

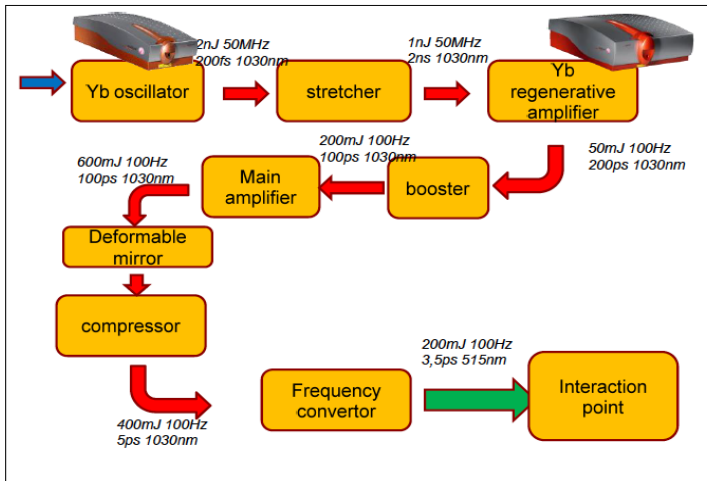


Acceptance of GBS devices/components



ACP Systems, Amplitude Systems, France

Interaction laser IP1 – delivery of configuration able to provide pulses of $100\mu\text{J}$ at 100Hz repetition rate and 515nm wavelength.



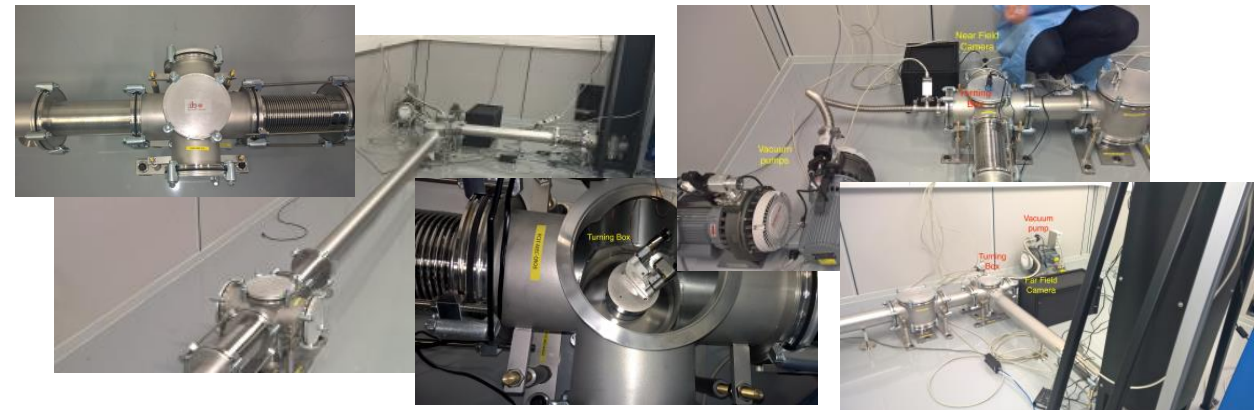
Amplitude Technologies, Lisses, France

Photocathode laser: stretcher, 100Hz regenerative amplifier, 100Hz multi-pass pre-amplifier, 2 x 100Hz multi-pass amplifiers, compressor, pump lasers.

Tests of module were successful being able to produce the 32 pulses separated at 16ns with an intensity fluctuations below 5%.

LAL CNRS, Orsay, France

Laser beam transport lines for photocathode laser and IP1.





Thank You for Your Attention

www.eli-np.ro

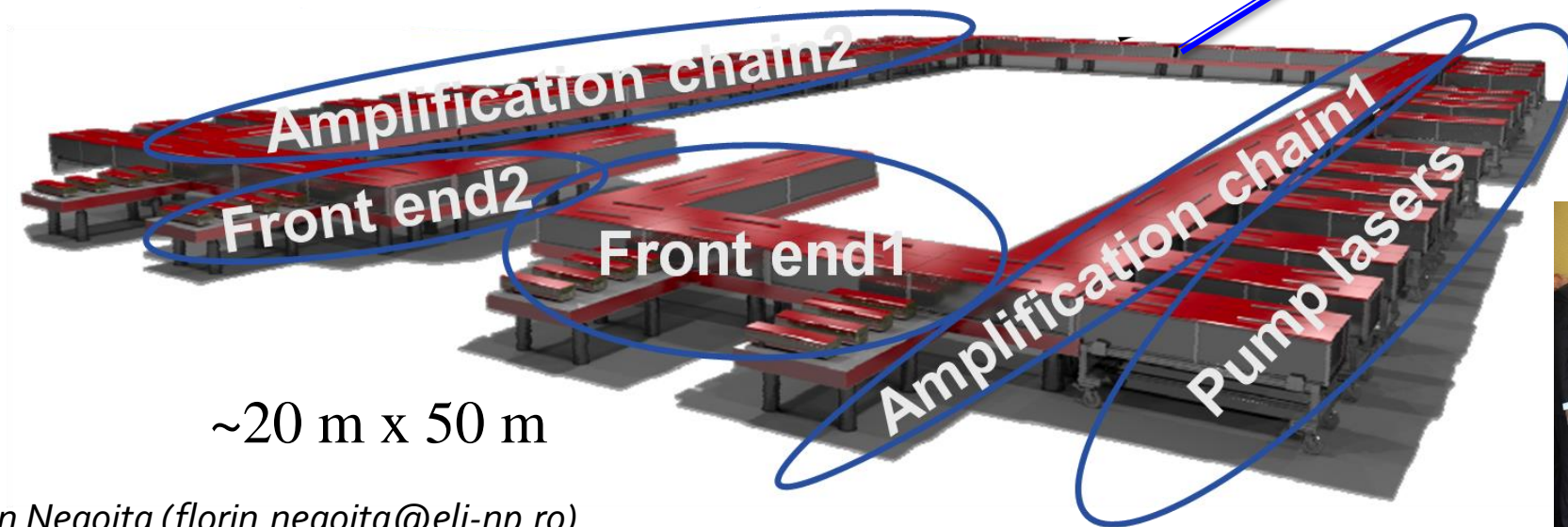
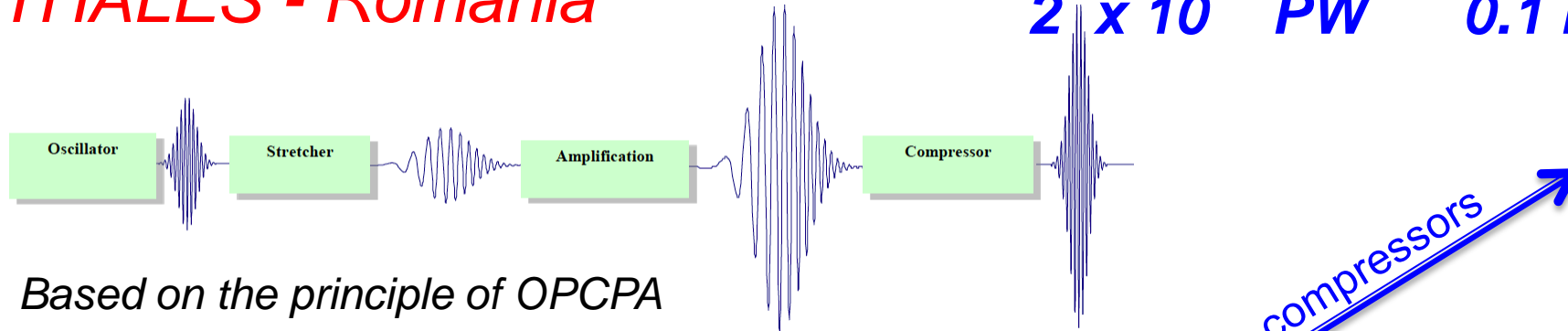
ELI-NP High Power Laser System



THALES – France
THALES - Romania

2013-2018

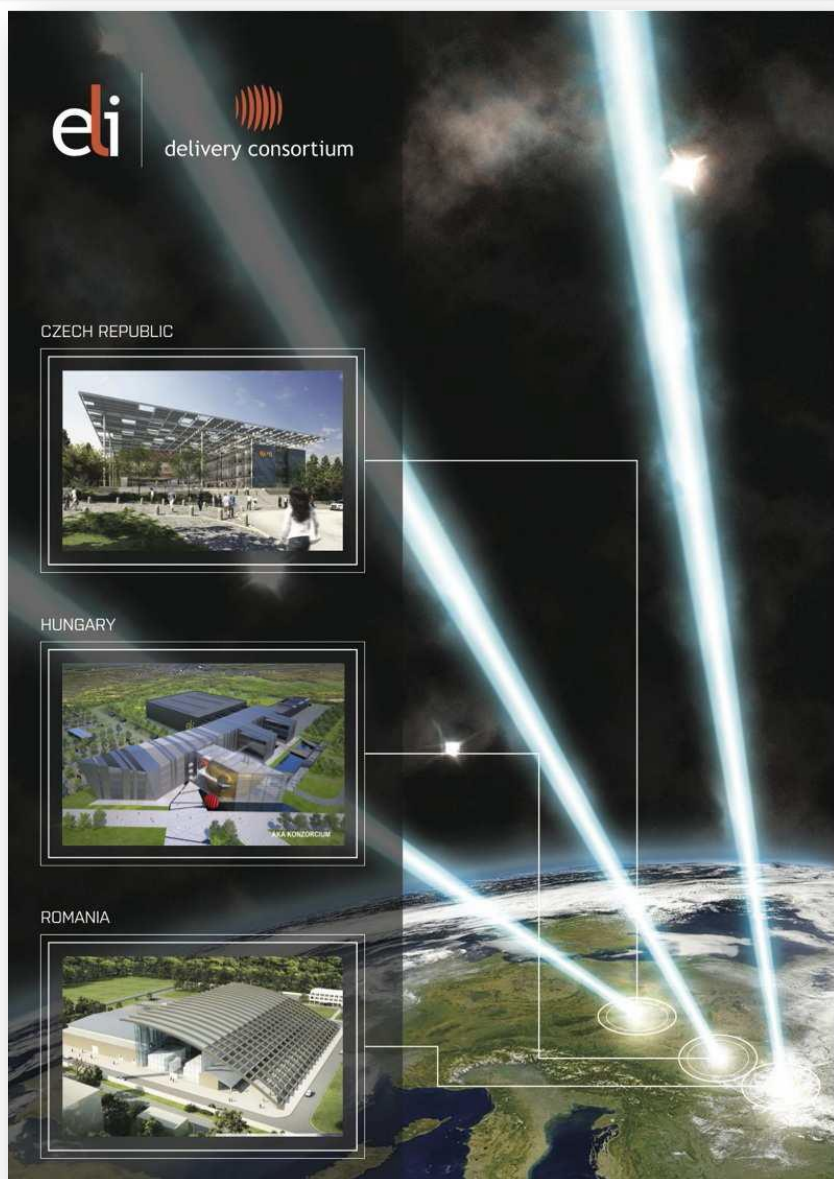
2 x 0.1 PW 10Hz
2 x 1 PW 1 Hz
2 x 10 PW 0.1 Hz



~20 m x 50 m



Extreme Light Infrastructure (ELI)



the world's first international laser research infrastructure

pan-European distributed research infrastructure based presently on 3 facilities in CZ, HU and RO

ELI-Beamlines, Prague, CZ

High-Energy Beam Facility
development and application of ultra-short pulses of high-energy particles and radiation

ELI-ALPS, Szeged, HU

Attosecond Laser Science Facility
new regimes of time resolution

ELI-NP, Magurele, RO

Nuclear Physics Facility with ultra-intense laser and brilliant gamma beams (up to 20 MeV)
novel photonuclear studies

ELI Roadmap

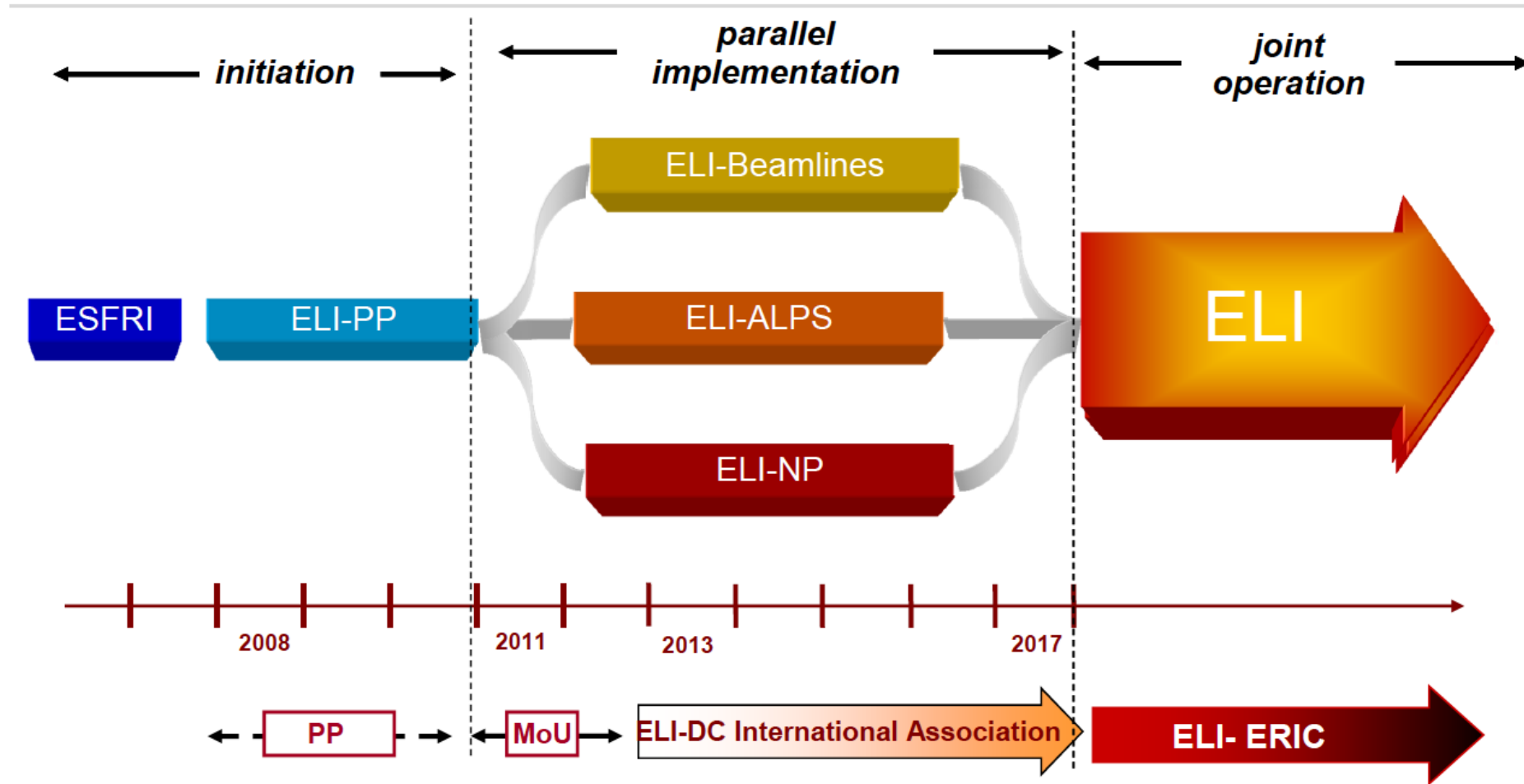
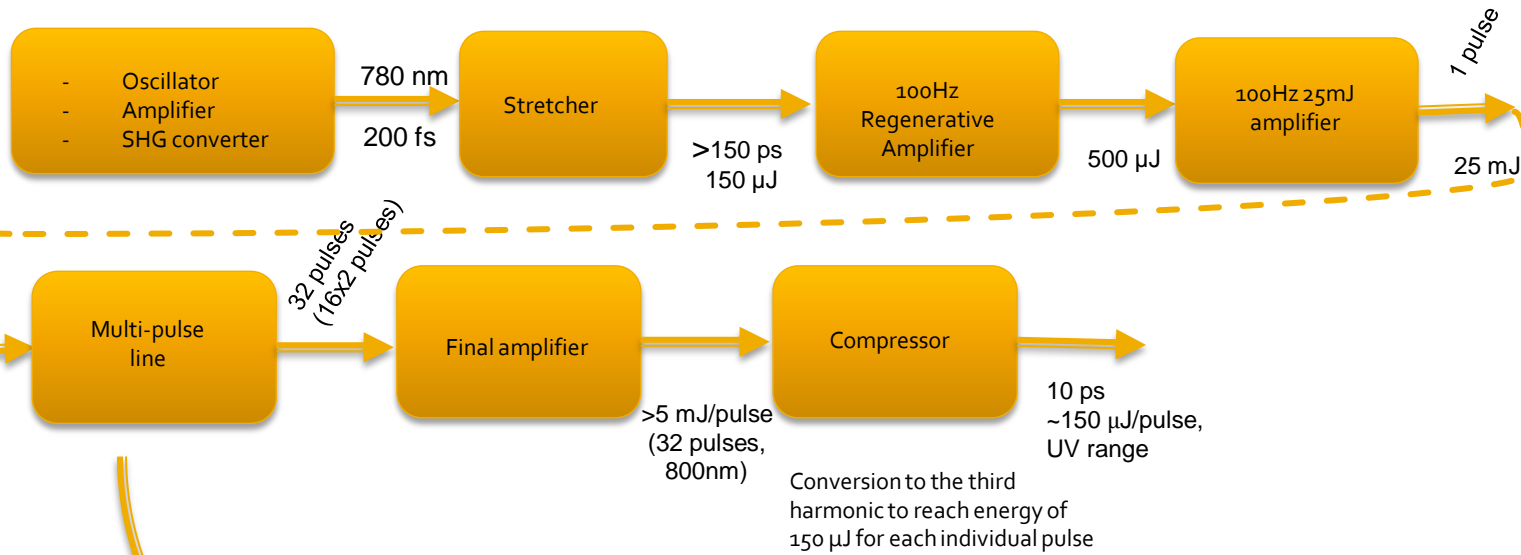
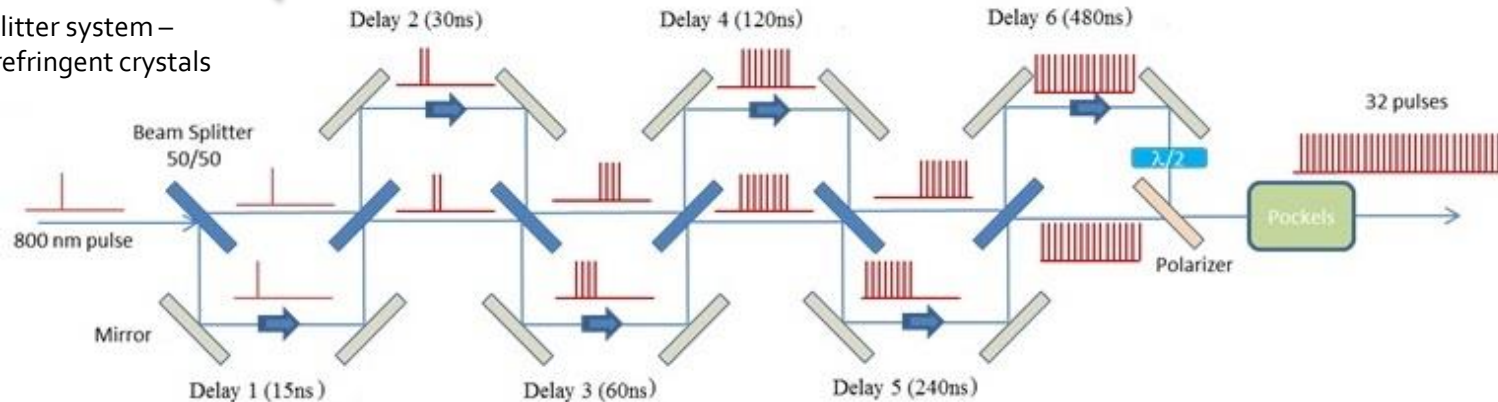


Photo-gun laser

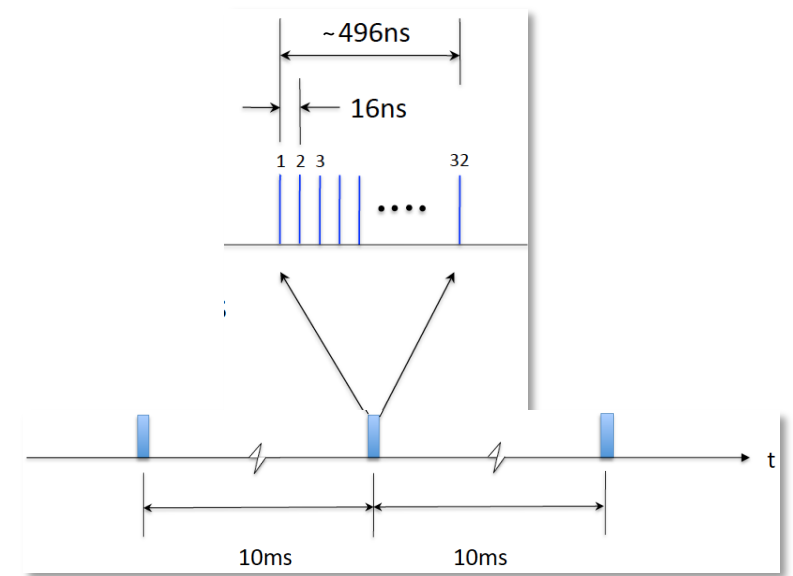


producing 32 replica (before the last amplifier)

Splitter system – birefringent crystals



Time structure of the electron beam

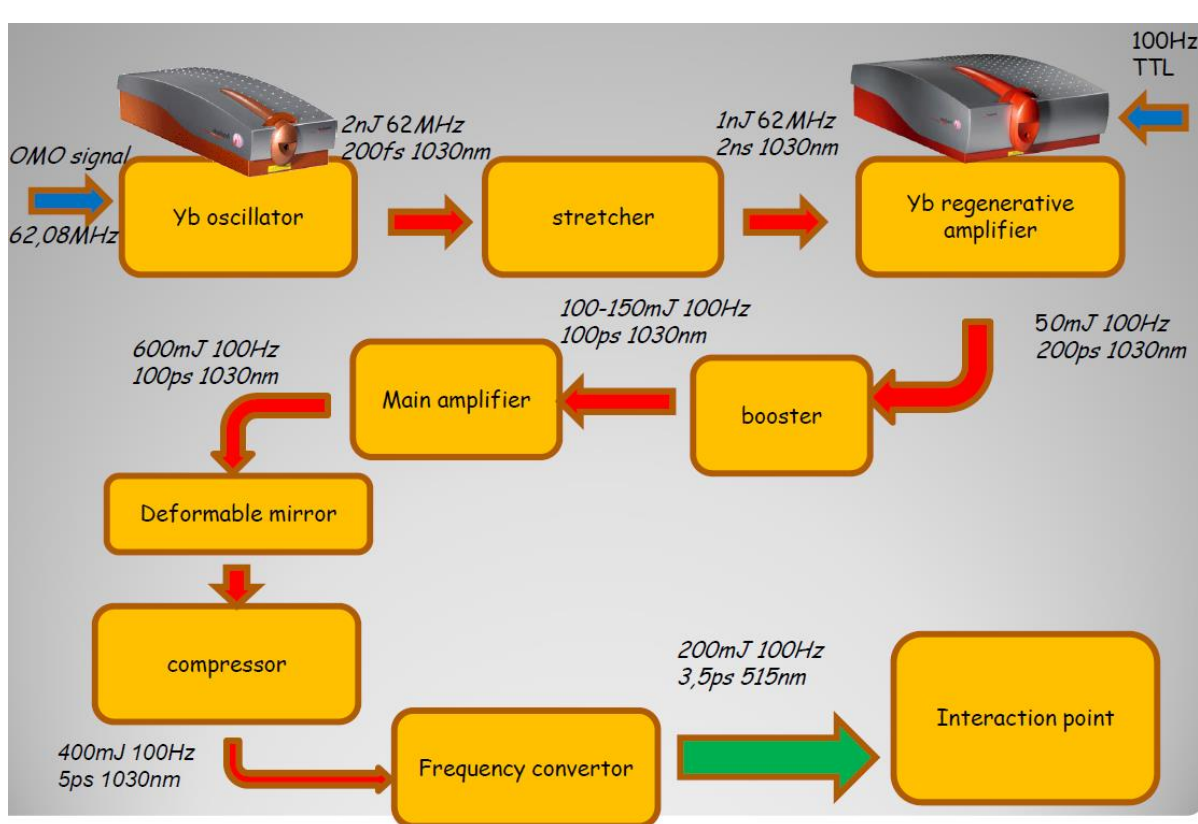


32 laser pulses separated by 16ns @ 100Hz repetition rate with ~10ps pulse duration

Interaction Points Lasers

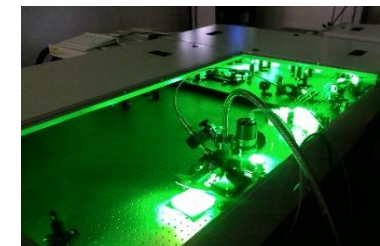


Interaction Laser Architecture



Interaction Lasers: cryo-cooled Yb:YAG

	Low Energy Interaction	High Energy Interaction
Pulse Energy [J]	0.2	2 x 0.2
Wavelength [nm]	515	515
FWHM Pulse length [ps]	3.5	3.5
Repetition Rate [Hz]	100	100
M ²	≤ 1.2	≤ 1.2
Focal spot size w ₀ [μm]	28	28
Bandwidth [rms]	0.1%	0.1%
Pointing Stability [μrad]	1	1
Synchronization to external clock	< 1 ps	< 1ps
Pulse energy stability	1%	1%



Gamma Beam vs. Energy

Simulated gamma beams for different energies

Photon Energy [MeV]	2.00	3.45	9.87	19.5
# photons / shot within FWHM bdw.	$< 1.2 \cdot 10^5$	$< 1.1 \cdot 10^5$	$< 2.6 \cdot 10^5$	$< 2.5 \cdot 10^5$
# photons / sec within FWHM bdw.	$< 4.0 \cdot 10^8$	$< 3.7 \cdot 10^8$	$< 8.3 \cdot 10^8$	$< 8.1 \cdot 10^8$
Source rms size [μm]	12	11	11	10
Source rms divergence [μrad]	≤ 140	≤ 100	≤ 50	≤ 40
Pulse length (rms) [ps]	0.92	0.91	0.95	0.90

GBS Linac



High quality gamma beam -> requires high quality electron beam

- Low emittance, low energy spread, and high beam charge
- To increase the gamma flux we need to increase the number of collision per second.

100 Hz repetition rate
Multi bunch

- Dumping of HOM dipole modes in RF structures to avoid BBU (beam break-up) instabilities
- Compensation of beam loading effects
- Accurate thermal design (high average dissipated power)

- > Waveguide dumping system with silicon-carbide (SiC) RF loads
- > amplitude modulation of the input RF power along the e⁻ beam train to reduce the energy spread
- > each structure has 14 water cooling channels for temperature stabilization; water flow of 66 litre /min

compact system

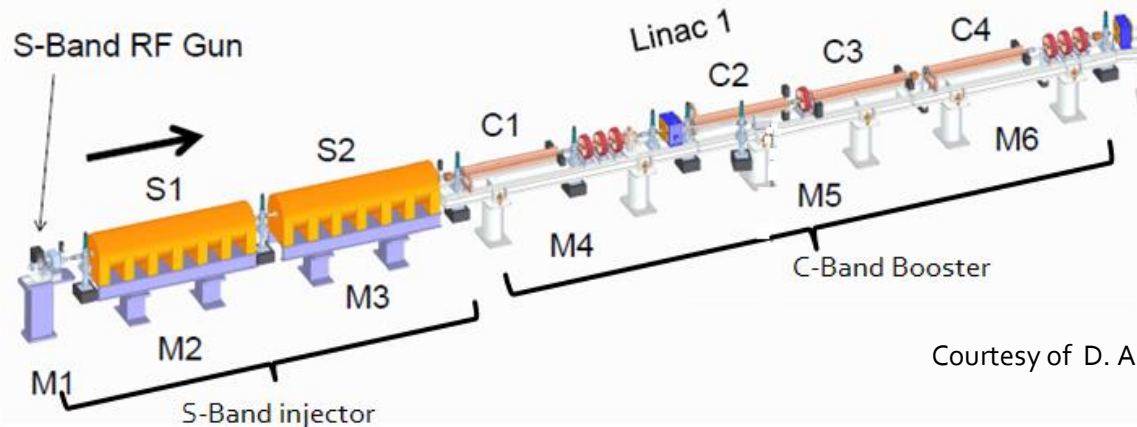
High gradient

C-band linac combined with S-band Injector

Multi-bunch mode -> wakefields (both longitudinal and transverse components $F \equiv F_{\parallel} + F_{\perp}$) -> affect the longitudinal (changes energy) and transverse (deflects trajectory) beam dynamics.

Longitudinal components -> **beam loading effects** -> increase of energy spread and decrease of accelerating field gradient in the structure.

Transverse components (BBU) -> drive instability along the train generating the **HOM dipole modes**. (off-axis beam trajectories)



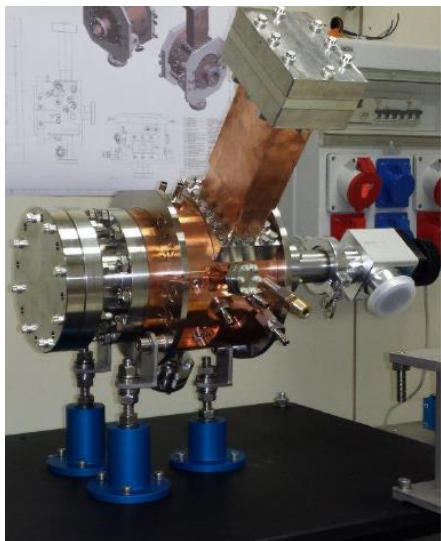
Courtesy of D. Alesini

Electron Gun

Gun sector - module 1

Laser-driven photocathode
1.6-cell standing-wave RF cavity,
working in S-band at 2.856 GHz.

Photocathode - (oxygen-free
high thermal conductivity)
OFHC Copper



Ti:Sa laser -

output: UV range (266nm), 10ps, 150μJ/pulse,
sequence of trains made of 32 pulses separated
by 16ns @ 100Hz repetition rate.

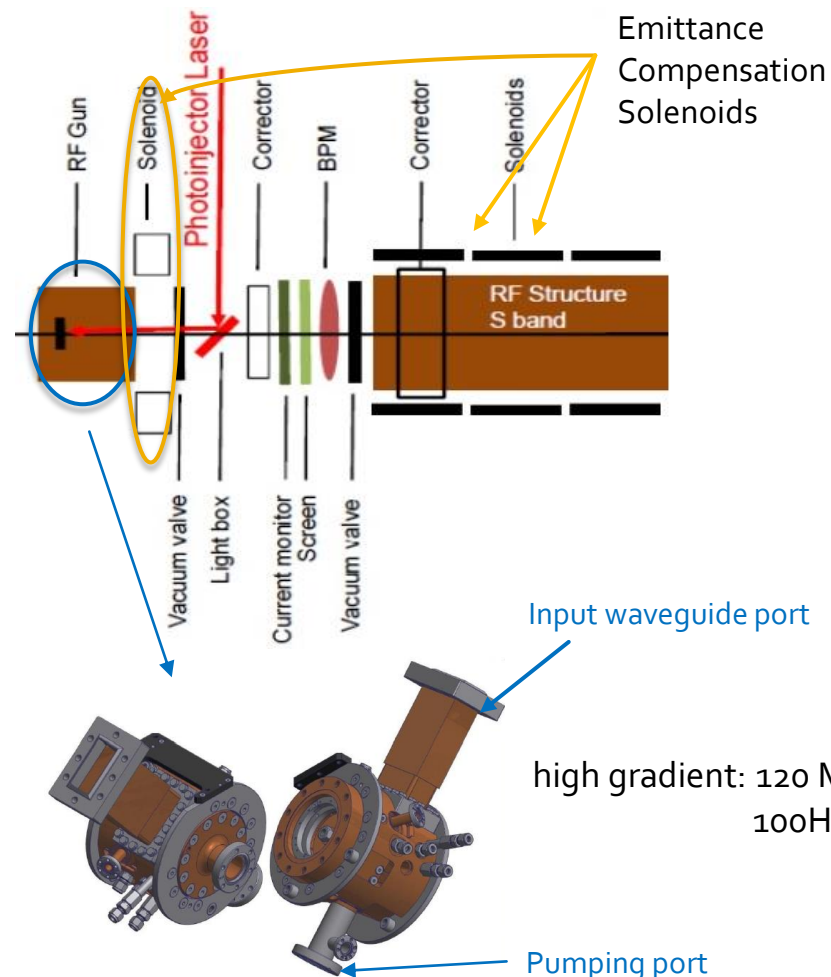


Photo-gun laser parameters at cathode:

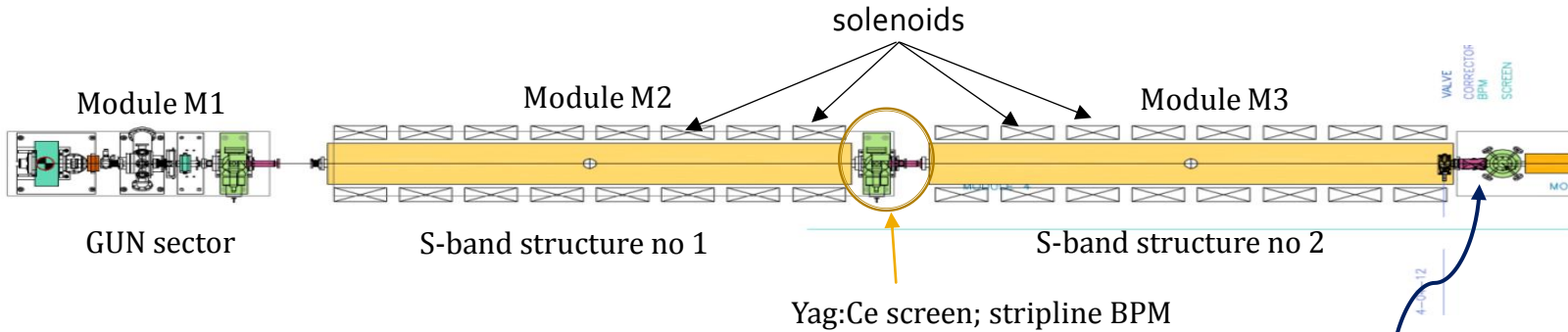
Laser pulse length (flat-top)	10 [ps]
Laser pulse rise/fall time FWHM	0,7 [ps]
Energy per pulse at 266 nm	150μJ
Laser spot size RMS radius on cathode	100-400 [μm]
Laser pulse energy jitter	2%
Time arrival jitter	<0.5 [ps]
Pointing jitter	<20 [μm]

Electron beam parameters:

Beam energy	5.7 [MeV]
Bunch charge	250 [pC]
Bunch length	~10 [ps]

S-band injector

S-band injector – 2 x Travelling Wave accelerating structures



manufacturer: RI Research Instruments GmbH

e^- beam energy: ~100 MeV
 bunch length: ~1 ps (~300 μ m)
 transverse normalized emittance ~0.4 μ rad

S-band acc. structure parameters

Structure type	Constant gradient, TW
Working Frequency	2.856 [GHz]
Number Cells / Structure length	86 / 3m
Phase advance between cells	$2\pi/3$
Nominal RF input power / Average dissipated power	40 [MW] / ~3.5kW
Accelerating gradient	22 [MV/m]
Quality factor (Q)	13000
Shunt Impedance per unit length	55 [M Ω /m]
RF input pulse length	1.5 [μ s]
Filling time	~850 [ns]

Long bunch at the photo-cathode -> to control the emittance growth due to space charge effects.

S-band injector – reduction of the bunch length by the velocity bunching technique.

Dual-symmetric feeding structures – minimization of the multipole effects generated by asymmetric feeding.

Beam loading effects - compensated with modulation of input RF power.

No evidence of HOM dipole modes in experimental measurements.

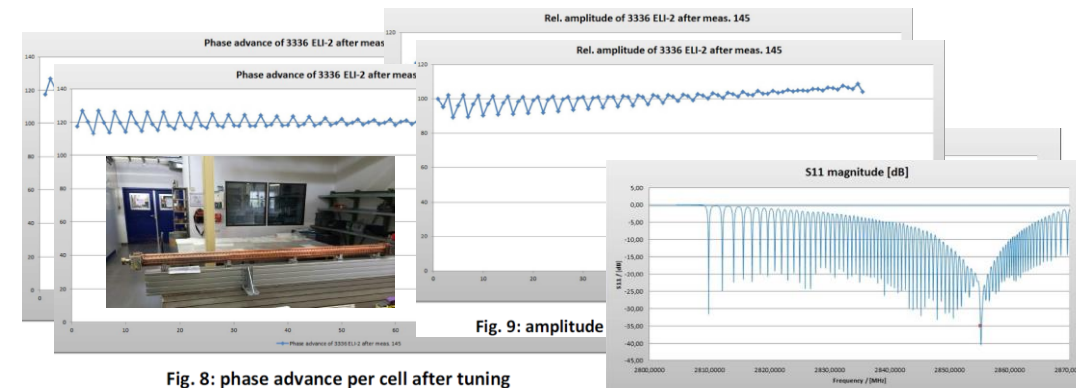


Fig. 8: phase advance per cell after tuning

Fig. 9: amplitude

Fig. 10: reflection coefficient at the input port after tuning

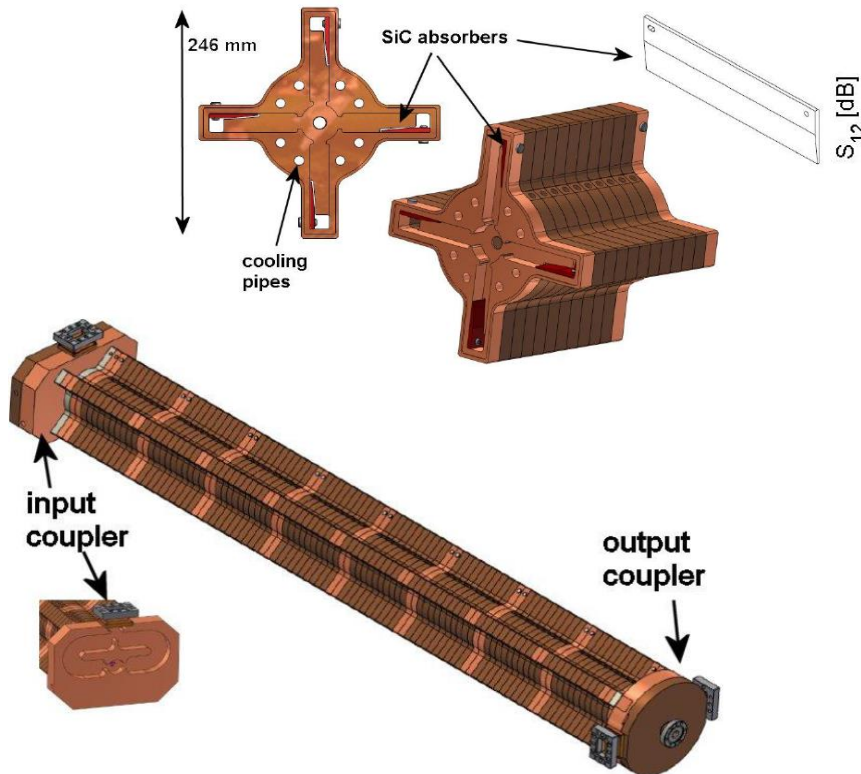
C-band LINAC



C-band linac – 12 x TW acc. structures

Effective damping of HOM dipoles modes

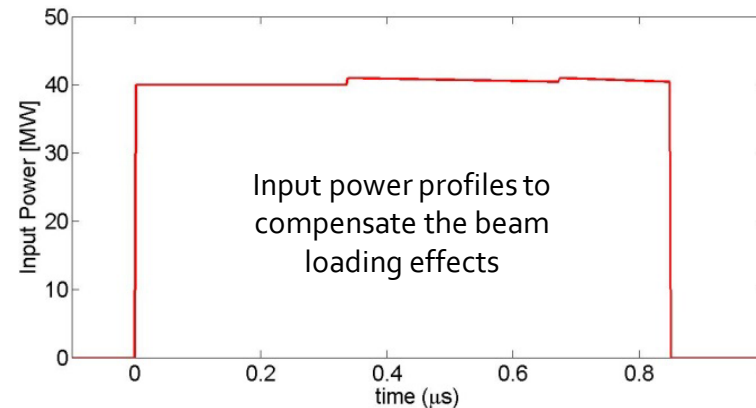
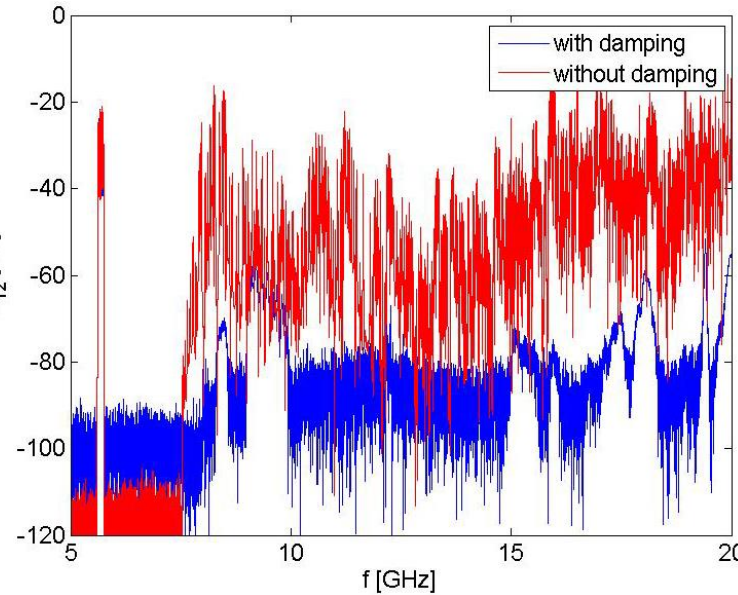
Waveguide dumping system - four waveguides in each cell -> excited dipole modes propagate and dissipate into RF loads.



Dual-symmetric feeding structures

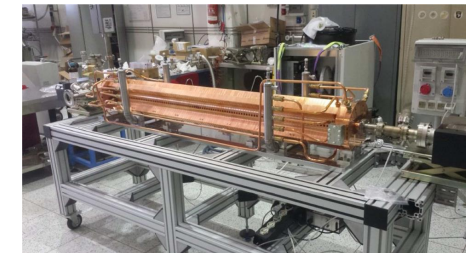


Transmission Coefficient



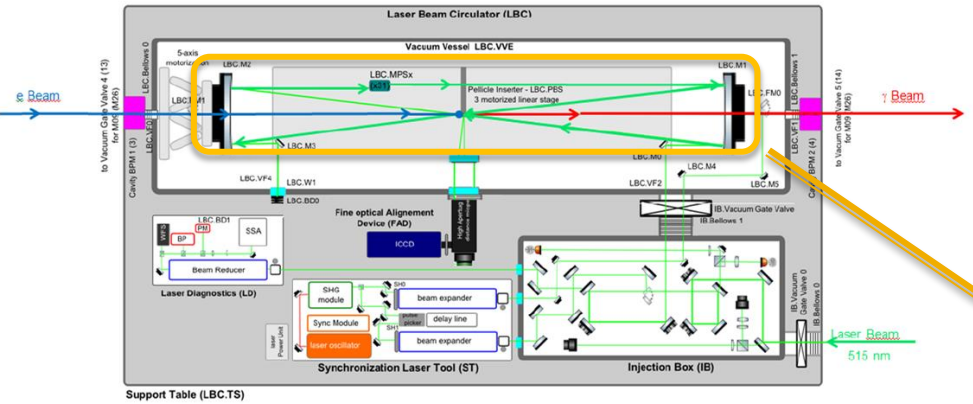
C-band acc. structure parameters

Structure type	Quasi-constant gradient, TW
Working Frequency	5.712 [GHz]
Number Cells / Structure length	102 + 1in + 1 out coupler / 1.8m
Phase advance between cells	$2\pi/3$
Nominal RF input power / Average dissipated power	40 [MW] / ~2.3kW
Average accelerating gradient	33 [MV/m]
Quality factor	8800
Shunt Impedance per unit length	74.5 [MΩ/m]
Max. RF input pulse length	0.8 [μs]
Filling time	310 [ns]
Working temperature	30 [°C]

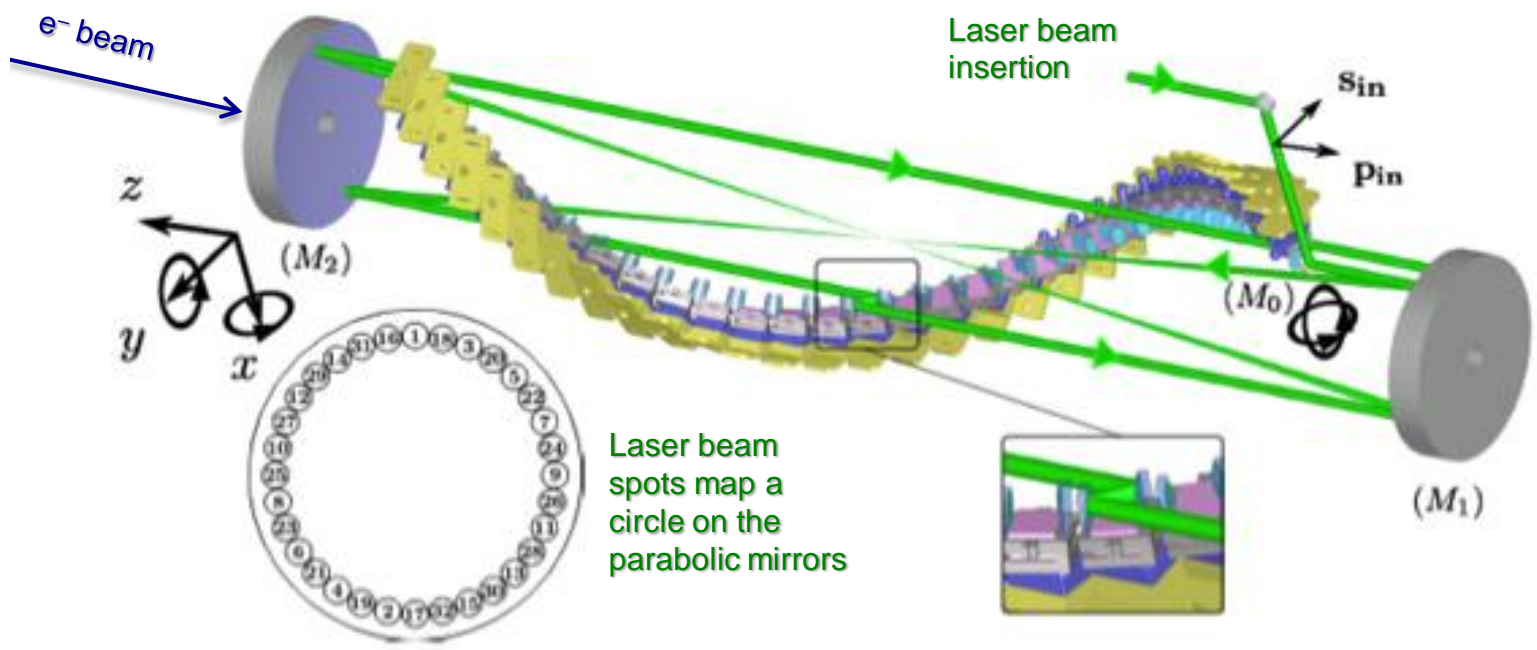


D.Alesini et al., "Design and RF Test of Damped C-band Accelerating Structures for the ELI-NP Linac" THPRI042, proceedings of IPAC2014, Dresden, Germany

Laser Recirculation at IP



'Dragon-shaped' Laser Recirculation



Provide 32 passes of an intense laser pulse @ 100 Hz

- Focusing the laser beam on the electron beam without optical aberrations
- Keeping a constant crossing angle between laser and electrons (7.5°)
- Synchronization to an ext. clock <1 ps
- Extreme mechanical precision – mirrors parallelism $\leq 10 \mu\text{rad}$; mirrors alignment tolerance $\leq 10 \mu\text{m}$
- High damage threshold optics, high level of cleanness and high vacuum required

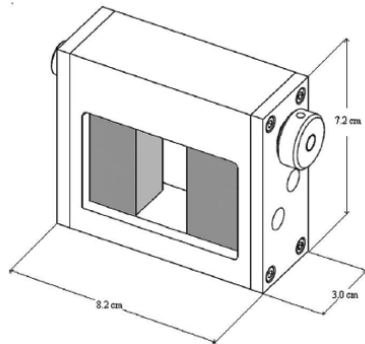
Gamma Beam Collimation and Diagnostics



Collimator System to obtain narrow bandwidth main requirements are:

- **Low transmission of gamma photons** (high density and atomic number)
- **Continuously adjustable aperture** (to adjust the energy bandwidth in the entire energy range)
- **Avoid contamination of the primary beam** with production of secondary radiation

Collimation aperture varies from 20mm to less than 1mm

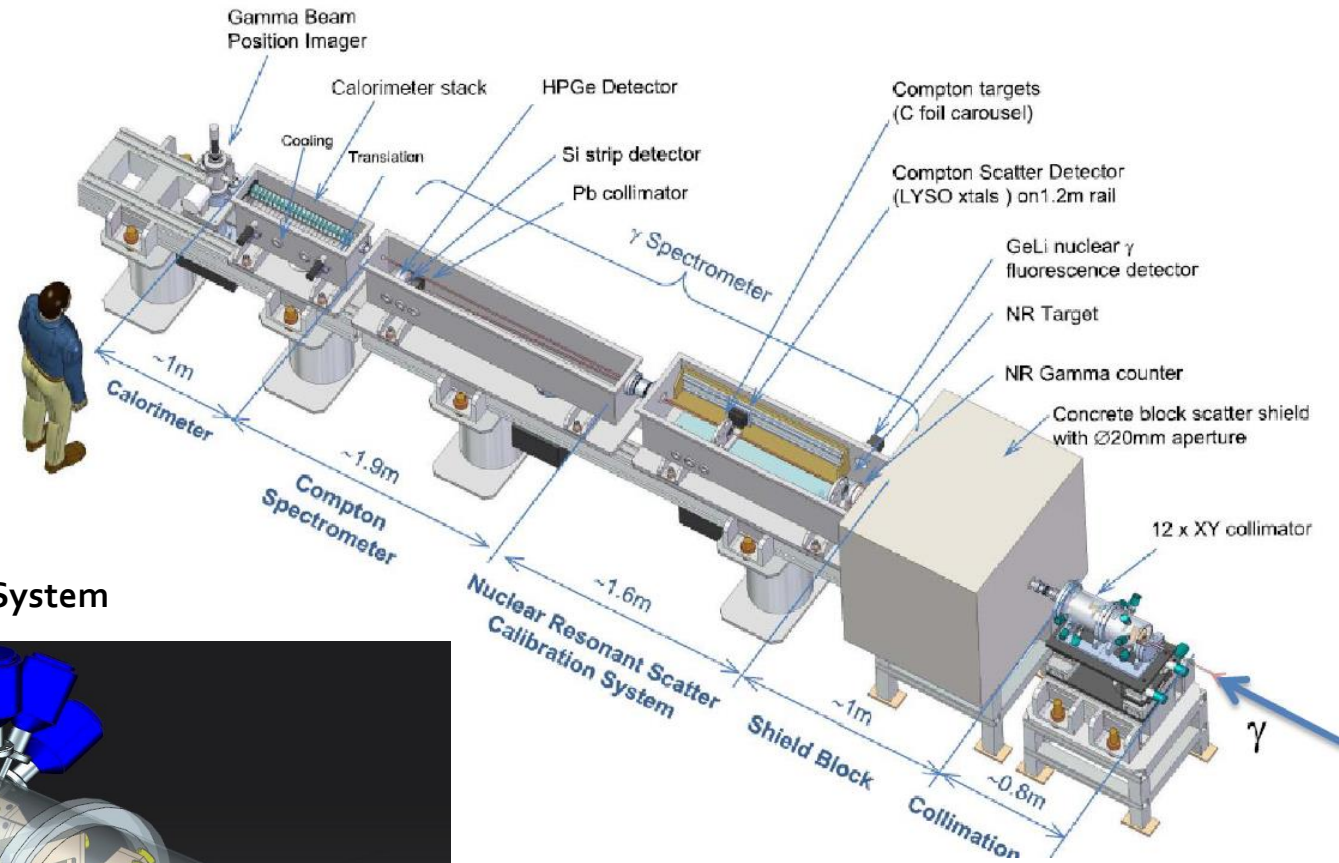
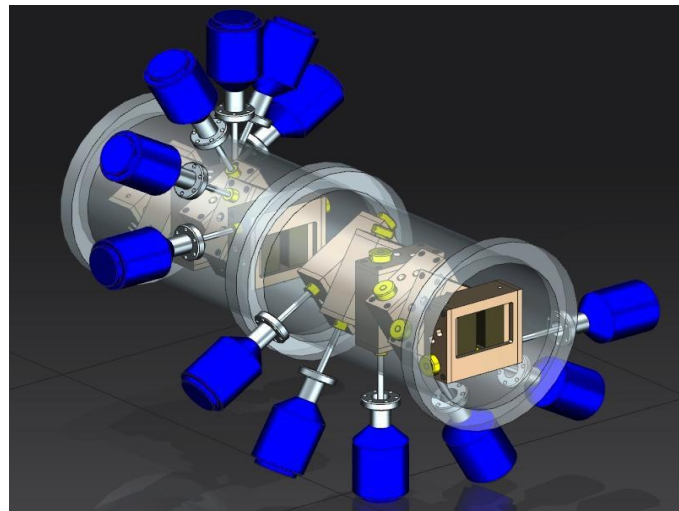


Tungsten slits – 20 mm thick

Low-energy configuration:
12 independent slits with 30° relative angle

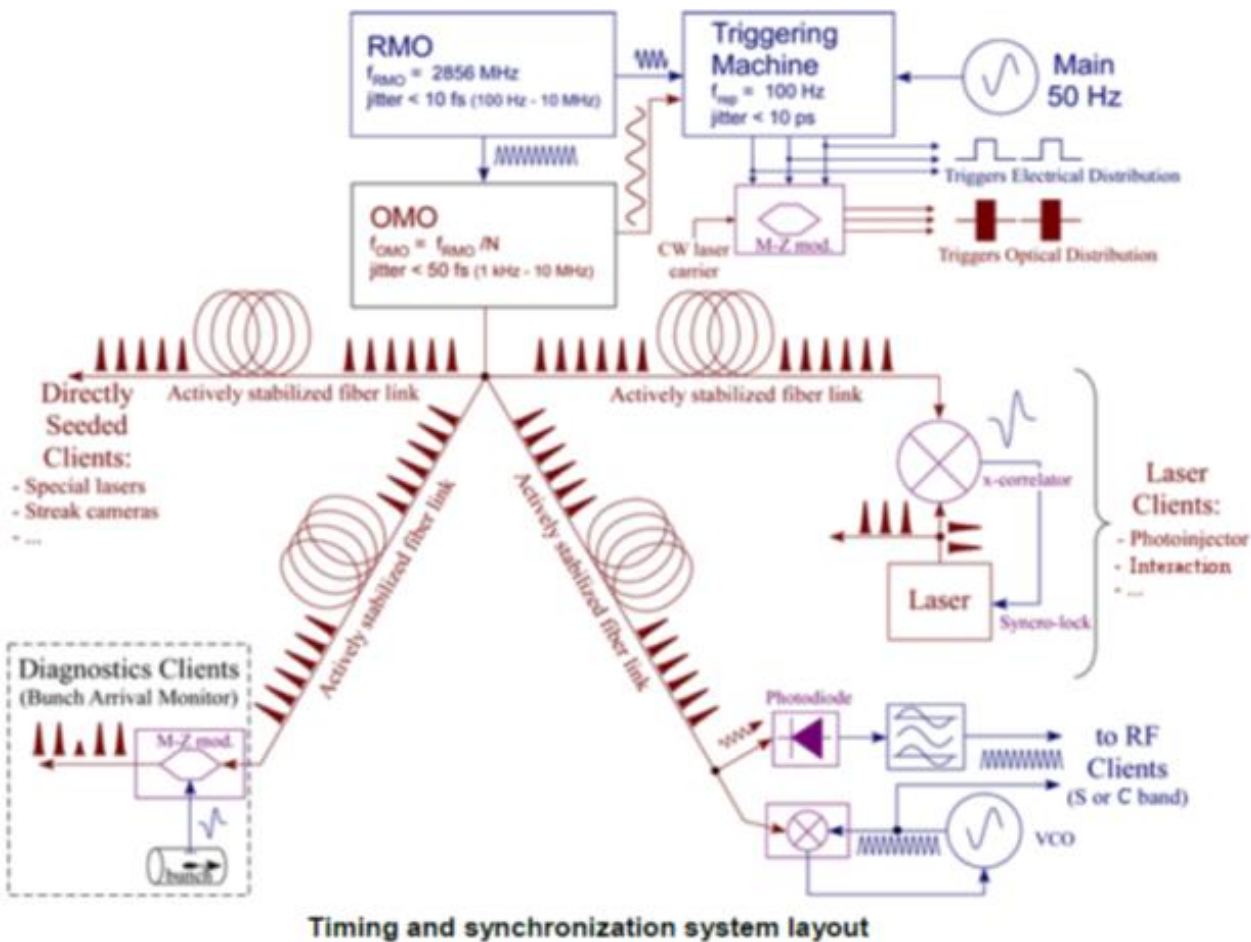
High-energy configuration:
14 independent slits with 25.7° relative angle

Collimator System



Gamma Beam Diagnostic System for:
 γ Beam characterization
 - energy, intensity, profile

Timing and Synchronization System



RMO - μ -wave crystal oscillator with ultra-low phase noise characteristics

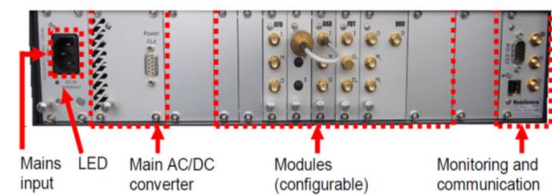
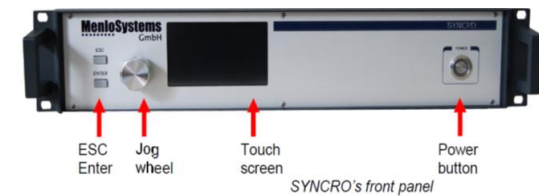
OMO – highly stable fiber-laser oscillator that encodes the reference timing information in the repetition rate of short optical pulse in the IR spectrum

Ultra-stable reference signal will be distributed to the clients through actively stabilized links. The stability of each link is ≈ 70 fs over any time scale.

Each individual clients will be locked to the local reference provided by the timing distribution systems. MENLO

Together with a continuous reference signal, low repetition rate trigger signals must be provided to some clients, which contain essentially the information on the timing of the macro pulses needed to prepare all the systems to produce and monitor the bunches and the radiation pulses (laser amplification pumps, klystron HV, bema diagnostics,...) The triggering system is a coarser timing line (≈ 10 ps stability, that can be distributed either optically or electrically.

COSYLAB (MRF)



Timing and Synchronization System

Laser systems synchronization

The reference signal is generated by an optical master oscillator (OMO) and transmitted to the end users by a stabilized fibre optic link.

The phase error is measured by optical mixing (cross-correlator). One pulse from the laser oscillator and one from the OMO overlap. The measured phase noise error is used to drive actuator to active control the oscillator's cavity length -> high frequency piezo-electric transducer (PZT) is associated to a lower frequency stepper motor driven optical delay line.

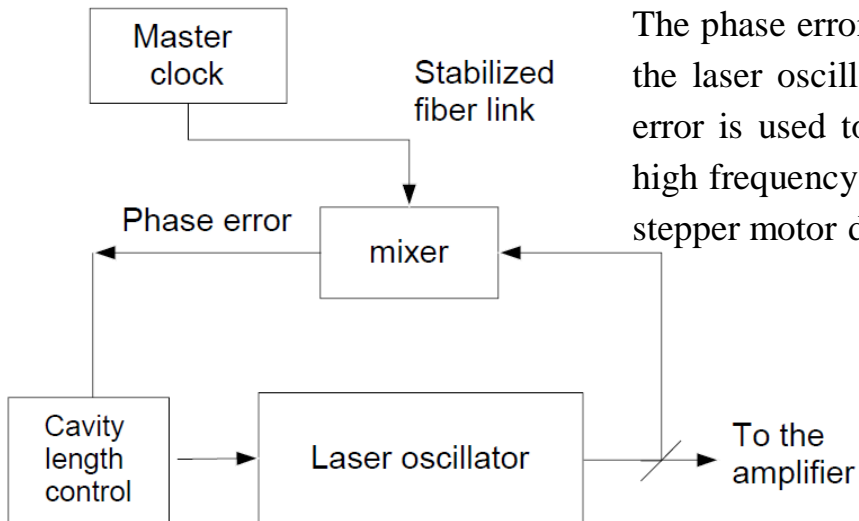


Fig. 102. Schematic of the laser oscillator phase locked loop

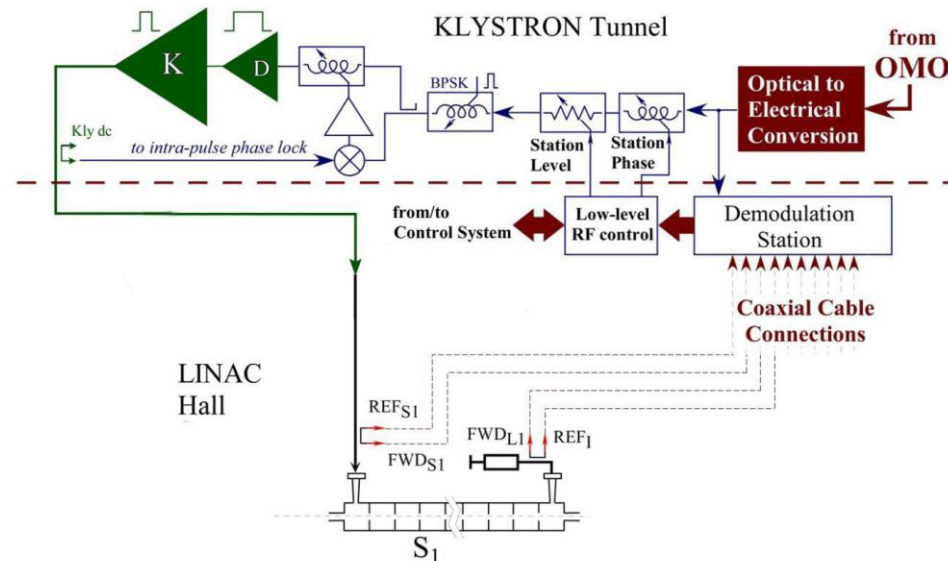


Fig. 104. Sketch of the ELI-NP single power station

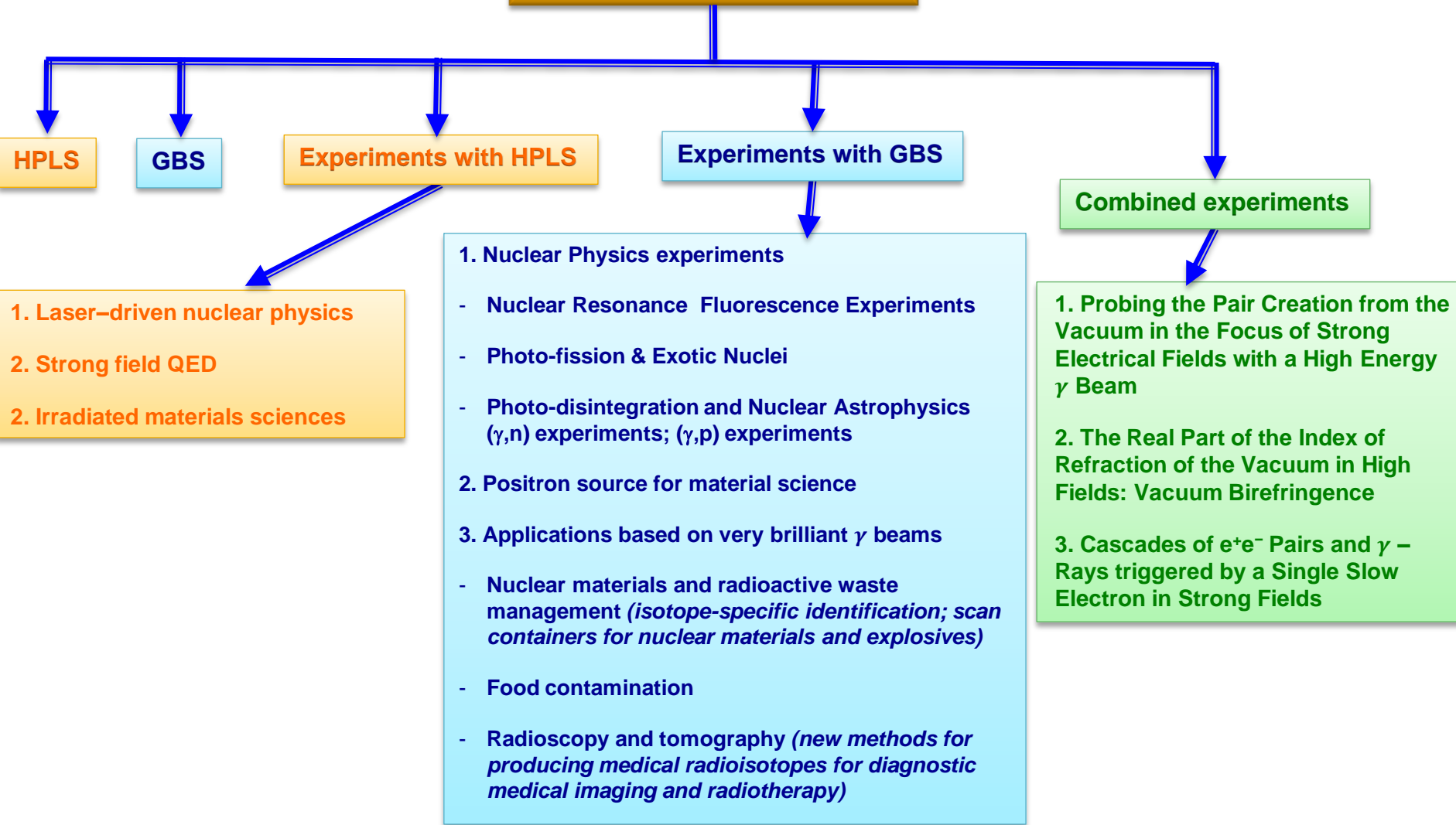
Synchronization of the RF clients

RF driving signal for all power sources will be locally extracted from the OMO reference transported to each station by stabilized phase links. The optical to electrical conversion will be accomplished by photodiodes. The same reference is used to demodulate various RF pulses sampled over the network, and the whole station is re-phased in real time on the base of the measured values.

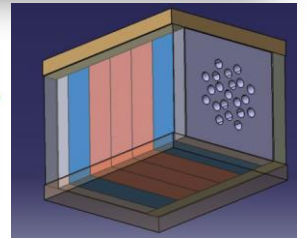
ELI-NP Nuclear Physics Research



Research Activities



Si DSSSD



4PIN – neutron ³He counter array

